



## 20 MHz, Second-Order, Isolated Delta-Sigma Modulator for Current-Shunt Measurement

Check for Samples: [AMC1204-Q1](#)

### FEATURES

- **Qualified for Automotive Applications**
- **AEC-Q100 Qualified With the Following Results**
  - Device Temperature Grade 1: –40°C to 125°C Ambient Operating Temperature Range
  - Device HBM ESD Classification Level H2
  - Device CDM ESD Classification Level C3B
- **±250-mV Input Voltage Range Optimized for Shunt Resistors**
- **Certified Digital Isolation:**
  - CSA, IEC60747-5-2, and UL1577 Approved
  - Isolation Voltage: 4250 V<sub>PEAK</sub>
  - Working Voltage: 1200 V<sub>PEAK</sub>
  - Transient Immunity: 15 kV/μs
- **Long Isolation Barrier Lifetime (see Application Report [SLLA197](#))**
- **High Electromagnetic Field Immunity (see Application Note [SLLA181A](#))**
- **Outstanding AC Performance:**
  - SNR: 84 dB (min)
  - THD: –80 dB (max)
- **Excellent DC Precision:**
  - INL: ±8 LSB (max)
  - Gain Error: ±2.5% (max)
- **External Clock Input for Easier Synchronization**
- **Fully Specified Over the Extended Automotive Temperature Range**

### APPLICATION

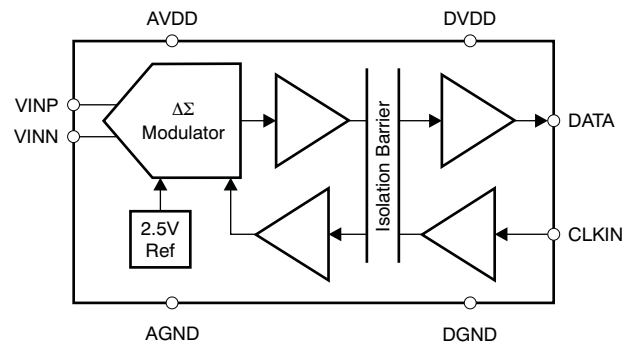
- **Shunt Resistor Based Current Sensing in:**
  - Motor Control
  - Green Energy
  - Inverter Applications
  - Uninterruptible Power Supplies

### DESCRIPTION

The AMC1204-Q1 is a 1-bit digital output, isolated delta-sigma ( $\Delta\Sigma$ ) modulators that can be clocked at up to 20 MHz. The digital isolation of the modulator output is provided by a silicon dioxide (SiO<sub>2</sub>) barrier that is highly resistant to magnetic interference. This barrier has been certified to provide basic galvanic isolation of up to 4250 V<sub>PEAK</sub> according to UL1577, IEC60747-5-2, and CSA standards or specifications.

The AMC1204-Q1 provides a single-chip solution for measuring the small signal of a shunt resistor across an isolated barrier. These types of resistors are typically used to sense currents in motor control inverters, green energy generation systems, and other industrial applications. The AMC1204-Q1 differential inputs easily connect to the shunt resistor or other low-level signal sources. An internal reference eliminates the need for external components. When used with an appropriate external digital filter, an effective number of bits (ENOB) of 14 is achieved at a data rate of 78 kSPS.

A 5-V analog supply (AVDD) is used by the modulator while the isolated digital interface operates from a 3-V, 3.3-V, or 5-V supply (DVDD). The AMC1204-Q1 is available in SO-16 (DW) packages and are specified from –40°C to 125°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### ORDERING INFORMATION<sup>(1)</sup>

| ORDERABLE PART NUMBER <sup>(2)</sup> | MODULATOR CLOCK (MHz) | DIGITAL SUPPLY     | CLOCK SOURCE | INL (LSB) | GAIN ERROR (%) | THD (dB) |
|--------------------------------------|-----------------------|--------------------|--------------|-----------|----------------|----------|
| AMC1204QDWRQ1                        | 20                    | 3 V, 3.3 V, or 5 V | External     | ±8        | ±2.5           | –80      |

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder on [www.ti.com](http://www.ti.com)

(2) Package drawings, thermal data, and symbolization are available at [www.ti.com/packaging](http://www.ti.com/packaging).

### ABSOLUTE MAXIMUM RATINGS<sup>(1)</sup>

Over the operating ambient temperature range, unless otherwise noted.

| PARAMETER  |  | AMC1204-Q1 |            | UNIT |
|--|--|------------|------------|------|
|  |  | MIN        | MAX        |      |
| Supply voltage, AVDD to AGND or DVDD to DGND         |  | –0.3       | 6          | V    |
| Analog input voltage at VINP, VINN                   |  | AGND – 0.5 | AVDD + 0.5 | V    |
| Digital input voltage at CLKIN                       |  | DGND – 0.3 | DVDD + 0.3 | V    |
| Input current to any pin except supply pins          |  | –10        | 10         | mA   |
| Maximum virtual junction temperature, T <sub>J</sub> |  |            | 150        | °C   |
| Operating ambient temperature range, T <sub>OA</sub> |  | –40        | 125        | °C   |
| Electrostatic discharge (ESD), all pins              | Human body model (HBM) AEC-Q100 Classification Level H2      | –2000      | 2000       | V    |
|  | Charged device model (CDM) AEC-Q100 Classification Level C3B | –750       | 750        | V    |

(1) Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under the [Electrical Characteristics](#) is not implied. Exposure to absolute maximum rated conditions for extended periods may affect device reliability.

### THERMAL INFORMATION

| THERMAL METRIC <sup>(1)</sup> |  | AMC1204-Q1   | UNIT |
|-------------------------------|--|--------------|------|
|                               |  | DW (16 PINS) |      |
| θ <sub>JA</sub>               | Junction-to-ambient thermal resistance       | 78.5         | °C/W |
| θ <sub>JCTop</sub>            | Junction-to-case (top) thermal resistance    | 41.3         |      |
| θ <sub>JB</sub>               | Junction-to-board thermal resistance         | 50.2         |      |
| ψ <sub>JT</sub>               | Junction-to-top characterization parameter   | 11.5         |      |
| ψ <sub>JB</sub>               | Junction-to-board characterization parameter | 41.2         |      |
| θ <sub>JCbot</sub>            | Junction-to-case (bottom) thermal resistance | n/a          |      |

(1) For more information about traditional and new thermal metrics, see the *IC Package Thermal Metrics* application report, [SPRA953](#).

## REGULATORY INFORMATION

| VDE/IEC                              | CSA  | UL  |
|--------------------------------------|--|---|
| Certified according to IEC 60747-5-2 | Approved under CSA component acceptance notice | Recognized under 1577 component recognition program |
| File number: 40016131                | File number: 2350550                           | File number: E181974                                |

## IEC SAFETY LIMITING VALUES

Safety limiting intends to prevent potential damage to the isolation barrier upon failure of input or output (I/O) circuitry. A failure of the I/O circuitry can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier, potentially leading to secondary system failures. The safety-limiting constraint is the operating virtual junction temperature range specified in the [Absolute Maximum Ratings](#) table. The power dissipation and junction-to-air thermal impedance of the device installed in the application hardware determine the junction temperature. The assumed junction-to-air thermal resistance in the [Thermal Information](#) table is that of a device installed in the JESD51-3, *Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages* and is conservative. The power is the recommended maximum input voltage times the current. The junction temperature is then the ambient temperature plus the power times the junction-to-air thermal resistance.

| PARAMETER                                     | TEST CONDITIONS   | MIN | TYP | MAX | UNIT             |
|---|---|-----|-----|-----|------------------|
| $I_S$ Safety input, output, or supply current | $\theta_{JA} = 78.5^\circ\text{C/W}$ , $V_I = 5.5\text{ V}$ ,<br>$T_J = 150^\circ\text{C}$ , $T_A = 25^\circ\text{C}$ |     |     | 10  | mA               |
| $T_C$ Maximum case temperature                |   |     |     | 150 | $^\circ\text{C}$ |

## IEC 61000-4-5 RATINGS

| PARAMETER                 | TEST CONDITIONS   | VALUE      | UNIT |
|---------------------------|---|------------|------|
| $V_{IOSM}$ Surge immunity | 1.2/50 $\mu\text{s}$ voltage surge and 8/20 $\mu\text{s}$ current surge | $\pm 6000$ | V    |

## IEC 60664-1 RATINGS

| PARAMETER                   | TEST CONDITIONS                                      | SPECIFICATION |
|-----------------------------|--|---------------|
| Basic isolation group       | Material group                                       | II            |
| Installation classification | Rated mains voltage $\leq 150\text{ V}_{\text{RMS}}$ | I-IV          |
|                             | Rated mains voltage $< 300\text{ V}_{\text{RMS}}$    | I-IV          |
|                             | Rated mains voltage $< 400\text{ V}_{\text{RMS}}$    | I-III         |
|                             | Rated mains voltage $< 600\text{ V}_{\text{RMS}}$    | I-III         |

**ISOLATION CHARACTERISTICS**

| PARAMETER   |  | TEST CONDITIONS   | VALUE    | UNIT       |
|-------------|--|---|----------|------------|
| $V_{IORM}$  | Maximum working insulation voltage per IEC |   | 1200     | $V_{PEAK}$ |
| $V_{PD(t)}$ | Partial discharge test voltage per IEC     | $t = 1\text{ s}$ (100% production test),<br>partial discharge $< 5\text{ pC}$ | 2250     | $V_{PEAK}$ |
| $V_{IOTM}$  | Transient overvoltage                      | $t = 60\text{ s}$ (qualification test)  | 4250     | $V_{PEAK}$ |
|             |  | $t = 1\text{ s}$ (100% production test)                                       | 5100     | $V_{PEAK}$ |
| $R_S$       | Isolation resistance                       | $V_{IO} = 500\text{ V}$ at $T_S$  | $> 10^9$ | $\Omega$   |
| PD          | Pollution degree                           |   | 2        | Degrees    |

**ISOLATOR CHARACTERISTICS<sup>(1)</sup>**

| PARAMETER |  | TEST CONDITIONS   | MIN     | TYP         | MAX | UNIT     |
|-----------|--|---|---------|-------------|-----|----------|
| L(I01)    | Minimum air gap (clearance)                      | Shortest terminal to terminal distance through air  | 7.9     |             |     | mm       |
| L(I02)    | Minimum external tracking (creepage)             | Shortest terminal to terminal distance across the package surface   | 7.9     |             |     | mm       |
| CTI       | Tracking resistance (comparative tracking index) | DIN IEC 60112/VDE 0303 part 1   | $> 400$ |             |     | V        |
|           | Minimum internal gap (internal clearance)        | Distance through the insulation   | 0.014   |             |     | mm       |
| $R_{IO}$  | Isolation resistance                             | Input to output, $V_{IO} = 500\text{ V}$ , all pins on each side of the barrier tied together to create a two-terminal device, $T_A < 85^\circ\text{C}$ |         | $> 10^{12}$ |     | $\Omega$ |
|           |  | Input to output, $V_{IO} = 500\text{ V}$ , $100^\circ\text{C} \leq T_A < T_{A\text{ max}}$  |         | $> 10^{11}$ |     | $\Omega$ |
| $C_{IO}$  | Barrier capacitance input to output              | $V_I = 0.8\text{ V}_{PP}$ at 1 MHz  |         | 1.2         |     | pF       |
| $C_I$     | Input capacitance to ground                      | $V_I = 0.8\text{ V}_{PP}$ at 1 MHz  |         | 3           |     | pF       |

- (1) Creepage and clearance requirements should be applied according to the specific equipment isolation standards of a specific application. Care should be taken to maintain the creepage and clearance distance of the board design to ensure that the mounting pads of the isolator on the printed circuit board (PCB) do not reduce this distance. Creepage and clearance on a PCB become equal according to the measurement techniques shown in the [Isolation Glossary](#) section. Techniques such as inserting grooves and/or ribs on the PCB are used to help increase these specifications.

## ELECTRICAL CHARACTERISTICS

All minimum/maximum specifications at  $T_A = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ,  $AVDD = 4.5\text{ V}$  to  $5.5\text{ V}$ ,  $DVDD = 2.7\text{ V}$  to  $5.5\text{ V}$ ,  $V_{INP} = -250\text{ mV}$  to  $250\text{ mV}$ ,  $V_{INN} = 0\text{ V}$ , and  $\text{sinc}^3$  filter with  $\text{OSR} = 256$ , unless otherwise noted. Typical values are at  $T_A = 25^{\circ}\text{C}$ ,  $AVDD = 5\text{ V}$ , and  $DVDD = 3.3\text{ V}$ .

| PARAMETER                     |   | TEST CONDITIONS  | AMC1204-Q1                |      |            | UNIT   |
|-------------------------------|---|--|---------------------------|------|------------|--------|
|                               |   |  | MIN                       | TYP  | MAX        |        |
| T <sub>A</sub>                | Specified ambient temperature range         |  | −40                       |      | 125        | °C     |
| RESOLUTION                    |   |  |                           |      |            |        |
|                               | Resolution                                  |  | 16                        |      |            | Bits   |
| DC ACCURACY                   |   |  |                           |      |            |        |
| INL                           | Integral linearity error <sup>(1)</sup>     | T <sub>A</sub> = −40°C to 85°C                           | −8                        | ±2   | 8          | LSB    |
|                               |   | T <sub>A</sub> = −40°C to 125°C                          | −16                       | ±5   | 16         | LSB    |
| DNL                           | Differential nonlinearity <sup>(2)</sup>    |  | −1                        |      | 1          | LSB    |
| V <sub>OS</sub>               | Offset error <sup>(3)</sup>                 |  | −1                        | ±0.1 | 1          | mV     |
| TCV <sub>OS</sub>             | Offset error thermal drift                  |  | −3.5                      | ±1   | 3.5        | μV/°C  |
| G <sub>ERR</sub>              | Gain error <sup>(3)</sup>                   |  | −2.5                      | ±0.5 | 2.5        | %      |
| TCC <sub>ERR</sub>            | Gain error thermal drift                    |  |                           | ±30  |            | ppm/°C |
| PSRR                          | Power-supply rejection ratio                |  |                           | 79   |            | dB     |
| ANALOG INPUTS                 |   |  |                           |      |            |        |
| FSR                           | Full-scale differential voltage input range | V <sub>INP</sub> − V <sub>INN</sub>                      | ±320                      |      |            | mV     |
|                               | Specified FSR                               |  | −250                      |      | 250        | mV     |
| V <sub>CM</sub>               | Operating common-mode signal <sup>(2)</sup> |  | −160                      |      | AVDD       | mV     |
| C <sub>I</sub>                | Input capacitance to AGND                   | V <sub>INP</sub> or V <sub>INN</sub>                     | 7                         |      |            | pF     |
| C <sub>ID</sub>               | Differential input capacitance              |  | 3.5                       |      |            | pF     |
| R <sub>ID</sub>               | Differential input resistance               |  | 12.5                      |      |            | kΩ     |
| I <sub>IL</sub>               | Input leakage current                       | V <sub>INP</sub> − V <sub>INN</sub> = ±250 mV            | −10                       |      | 10         | μA     |
|                               |   | V <sub>INP</sub> − V <sub>INN</sub> = ±320 mV            | −50                       |      | 50         | μA     |
| CMTI                          | Common-mode transient immunity              |  | 15                        |      |            | kV/μs  |
| CMRR                          | Common-mode rejection ratio                 | V <sub>IN</sub> from 0 V to 5 V at 0 Hz                  | 108                       |      |            | dB     |
|                               |   | V <sub>IN</sub> from 0 V to 5 V at 100 kHz               | 114                       |      |            | dB     |
| EXTERNAL CLOCK                |   |  |                           |      |            |        |
| t <sub>CLKIN</sub>            | Clock period                                |  | 45.5                      | 50   | 200        | ns     |
| f <sub>CLKIN</sub>            | Input clock frequency                       |  | 5                         | 20   | 22         | MHz    |
| Duty <sub>CLKIN</sub>         | Duty cycle                                  | 5 MHz ≤ f <sub>CLKIN</sub> < 20 MHz                      | 40                        | 50   | 60         | %      |
|                               |   | 20 MHz ≤ f <sub>CLKIN</sub> ≤ 22 MHz                     | 45                        | 50   | 55         | %      |
| AC ACCURACY                   |   |  |                           |      |            |        |
| SINAD                         | Signal-to-noise + distortion                | f <sub>IN</sub> = 1 kHz, T <sub>A</sub> = −40°C to 105°C | 70                        | 87   |            | dB     |
|                               |   | f <sub>IN</sub> = 1 kHz, T <sub>A</sub> = −40°C to 125°C | 69                        | 87   |            | dB     |
| SNR                           | Signal-to-noise ratio                       | f <sub>IN</sub> = 1 kHz, T <sub>A</sub> = −40°C to 105°C | 83                        | 88   |            | dB     |
|                               |   | f <sub>IN</sub> = 1 kHz, T <sub>A</sub> = −40°C to 125°C | 82                        | 88   |            | dB     |
| THD                           | Total harmonic distortion                   | f <sub>IN</sub> = 1 kHz, T <sub>A</sub> = −40°C to 105°C |                           | −96  | −70        | dB     |
|                               |   | f <sub>IN</sub> = 1 kHz, T <sub>A</sub> = −40°C to 125°C |                           | −96  | −69        | dB     |
| SFDR                          | Spurious-free dynamic range                 | f <sub>IN</sub> = 1 kHz, T <sub>A</sub> = −40°C to 105°C | 72                        | 96   |            | dB     |
|                               |   | f <sub>IN</sub> = 1 kHz, T <sub>A</sub> = −40°C to 125°C | 71                        | 96   |            | dB     |
| DIGITAL INPUTS <sup>(2)</sup> |   |  |                           |      |            |        |
| I <sub>IN</sub>               | Input current                               | V <sub>IN</sub> = DVDD to DGND                           | −10                       |      | 10         | μA     |
| C <sub>IN</sub>               | Input capacitance                           |  | 5                         |      |            | pF     |
| CMOS logic family             |   |  | CMOS with Schmitt-trigger |      |            |        |
| V <sub>IH</sub>               | High-level input voltage                    | DVDD = 4.5 V to 5.5 V                                    | 0.7 DVDD                  |      | DVDD + 0.3 | V      |
| V <sub>IL</sub>               | Low-level input voltage                     | DVDD = 4.5 V to 5.5 V                                    | −0.3                      |      | 0.3 DVDD   | V      |

(1) Integral nonlinearity is defined as the maximum deviation from a straight line passing through the end-points of the ideal ADC transfer function expressed as number of LSBs or as a percent of the specified 500 mV input range.

(2) Ensured by design.

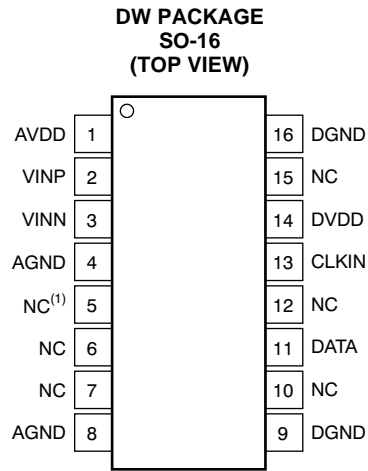
(3) Maximum values, including temperature drift, are ensured over the full specified temperature range.

**ELECTRICAL CHARACTERISTICS (continued)**

All minimum/maximum specifications at  $T_A = -40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ ,  $AVDD = 4.5\text{ V}$  to  $5.5\text{ V}$ ,  $DVDD = 2.7\text{ V}$  to  $5.5\text{ V}$ ,  $V_{INP} = -250\text{ mV}$  to  $250\text{ mV}$ ,  $V_{INN} = 0\text{ V}$ , and sinc<sup>3</sup> filter with  $\text{OSR} = 256$ , unless otherwise noted. Typical values are at  $T_A = 25^{\circ}\text{C}$ ,  $AVDD = 5\text{ V}$ , and  $DVDD = 3.3\text{ V}$ .

| PARAMETER                      |                                | TEST CONDITIONS                                  | AMC1204-Q1 |      |            | UNIT |
|--------------------------------|--------------------------------|--|------------|------|------------|------|
|                                |                                |  | MIN        | TYP  | MAX        |      |
| LVCMOS logic family            |                                |  | LVCMOS     |      |            |      |
| V <sub>IH</sub>                | High-level input voltage       | DVDD = 2.7 V to 3.6 V                            | 2          |      | DVDD + 0.3 | V    |
| V <sub>IL</sub>                | Low-level input voltage        | DVDD = 2.7 V to 3.6 V                            | −0.3       |      | 0.8        | V    |
| DIGITAL OUTPUTS <sup>(2)</sup> |                                |  |            |      |            |      |
| C <sub>OUT</sub>               | Output capacitance             |  | 5          |      |            | V    |
| C <sub>LOAD</sub>              | Load capacitance               |  | 30         |      |            | V    |
| CMOS logic family              |                                |  | CMOS       |      |            |      |
| V <sub>OH</sub>                | High-level output voltage      | DVDD = 4.5 V, I <sub>OH</sub> = −100 μA          | 4.4        |      |            | V    |
| V <sub>OL</sub>                | Low-level output voltage       | DVDD = 4.5 V, I <sub>OL</sub> = 100 μA           |            |      | 0.5        | V    |
| LVCMOS logic family            |                                |  | LVCMOS     |      |            |      |
| V <sub>OH</sub>                | High-level output voltage      | I <sub>OH</sub> = 20 μA                          | DVDD − 0.1 |      |            | V    |
|                                |                                | I <sub>OH</sub> = −4 mA,<br>2.7 V ≤ DVDD ≤ 3.6 V | DVDD − 0.4 |      |            | V    |
|                                |                                | I <sub>OH</sub> = −4 mA,<br>4.5 V ≤ DVDD ≤ 5.5 V | DVDD − 0.8 |      |            | V    |
| V <sub>OL</sub>                | Low-level output voltage       | I <sub>OL</sub> = 20 μA                          | 0.1        |      |            | V    |
|                                |                                | I <sub>OL</sub> = 4 mA                           | 0.4        |      |            | V    |
| POWER SUPPLY                   |                                |  |            |      |            |      |
| AVDD                           | High-side supply voltage       |  | 4.5        | 5    | 5.5        | V    |
| DVDD                           | Controller-side supply voltage |  | 2.7        | 3.3  | 5.5        | V    |
| I <sub>AVDD</sub>              | High-side supply current       | 4.5 V ≤ AVDD ≤ 5.5 V                             |            | 11   | 16         | mA   |
| I <sub>DVDD</sub>              | Controller-side supply current | 2.7 V ≤ DVDD ≤ 3.6 V                             |            | 2    | 4          | mA   |
|                                |                                | 4.5 V ≤ DVDD ≤ 5.5 V                             |            | 2.8  | 5          | mA   |
| P <sub>D</sub>                 | Power dissipation              | AVDD = 5.5 V, DVDD = 3.6 V                       |            | 61.6 | 102.4      | mW   |

## PIN CONFIGURATION



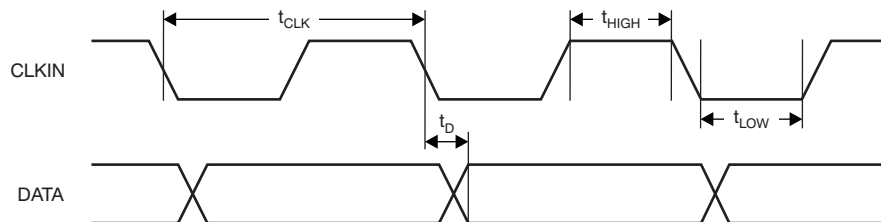
(1) NC = no internal connection.

## PIN DESCRIPTIONS

| PIN NAME | PIN NO.             | FUNCTION       | DESCRIPTION  |
|----------|---------------------|----------------|--|
| AVDD     | 1                   | Power          | High-side power supply   |
| VINP     | 2                   | Analog input   | Noninverting analog input  |
| VINN     | 3                   | Analog input   | Inverting analog input   |
| AGND     | 4, 8 <sup>(1)</sup> | Power          | High-side ground   |
| DGND     | 9, 16               | Power          | Controller-side ground   |
| DATA     | 11                  | Digital output | Modulator data output  |
| CLKIN    | 13                  | Digital input  | Modulator clock input  |
| DVDD     | 14                  | Power          | Controller-side power supply   |
| NC       | 5, 6, 7, 10, 12, 15 | —              | No internal connection; can be tied to any potential or left unconnected |

(1) Both pins are connected internally via a low-impedance path; thus, only one of the pins must be tied to the ground plane.

## TIMING INFORMATION



**Figure 1. Modulator Output Timing**

## TIMING CHARACTERISTICS FOR [Figure 1](#)

Over recommended ranges of supply voltage and operating free-air temperature, unless otherwise noted.

| PARAMETER  |   | MIN  | TYP | MAX | UNIT |
|------------|---|------|-----|-----|------|
| $t_{CLK}$  | CLKIN clock period                          | 45.5 | 50  | 200 | ns   |
| $t_{HIGH}$ | CLKIN clock high time                       | 20   | 25  | 120 | ns   |
| $t_{LOW}$  | CLKIN clock low time                        | 20   | 25  | 120 | ns   |
| $t_D$      | Delayed falling edge of CLKIN to DATA valid | 2    |     | 15  | ns   |

## TYPICAL CHARACTERISTICS

At AVDD = 5 V, DVDD = 3.3 V, VINP = –250 mV to 250 mV, VINN = 0 V, and sinc<sup>3</sup> filter with OSR = 256, unless otherwise noted.

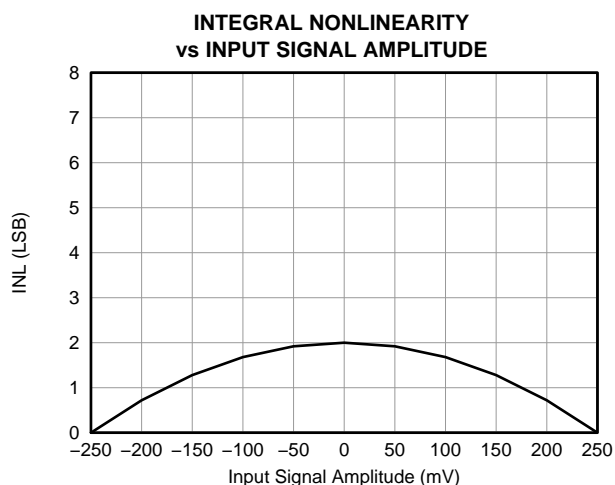


Figure 2.

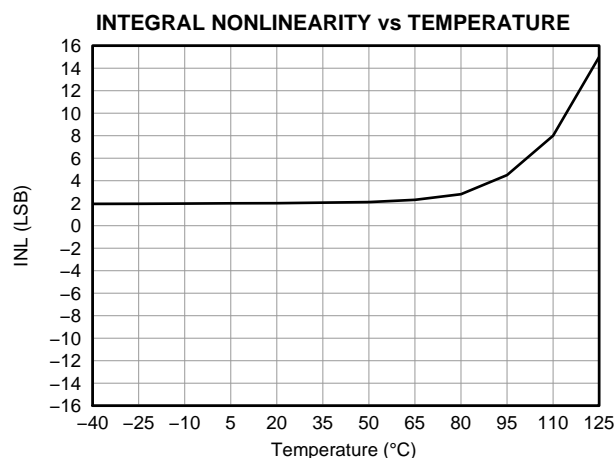


Figure 3.

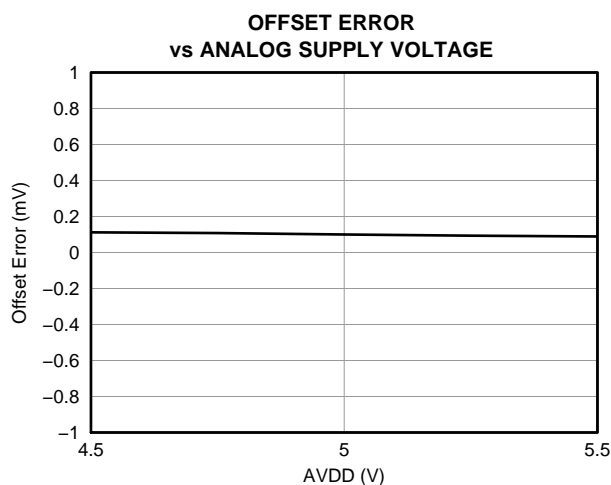


Figure 4.

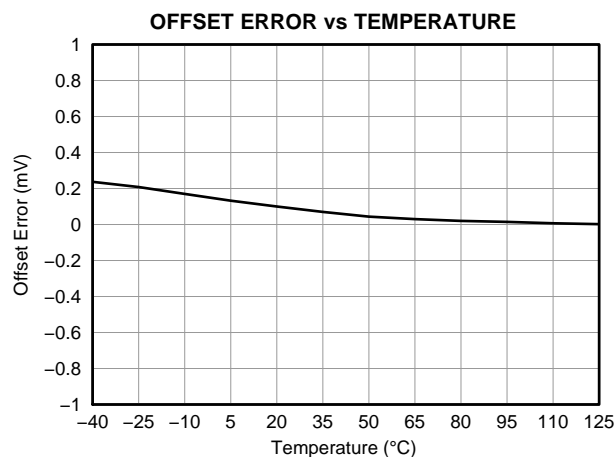


Figure 5.

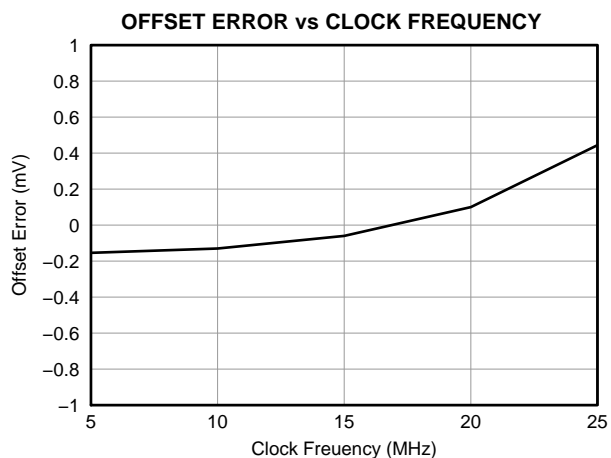


Figure 6.

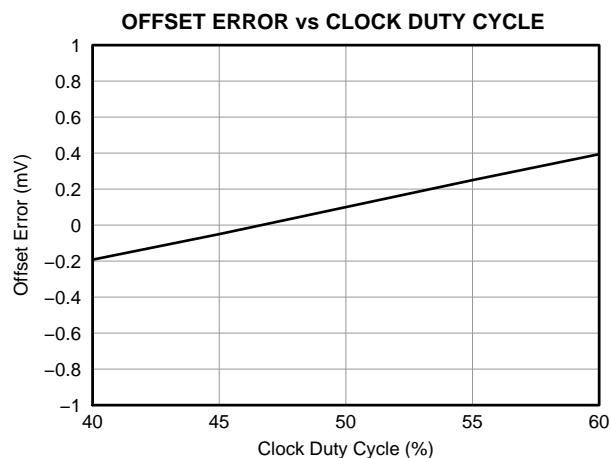


Figure 7.



## TYPICAL CHARACTERISTICS (continued)

At AVDD = 5 V, DVDD = 3.3 V, VINP = –250 mV to 250 mV, VINN = 0 V, and sinc<sup>3</sup> filter with OSR = 256, unless otherwise noted.

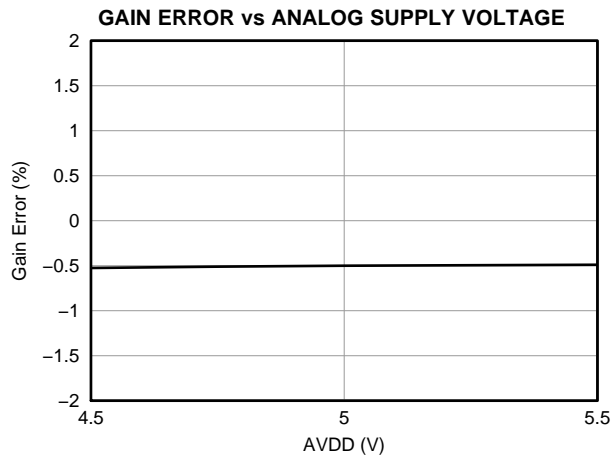


Figure 8.

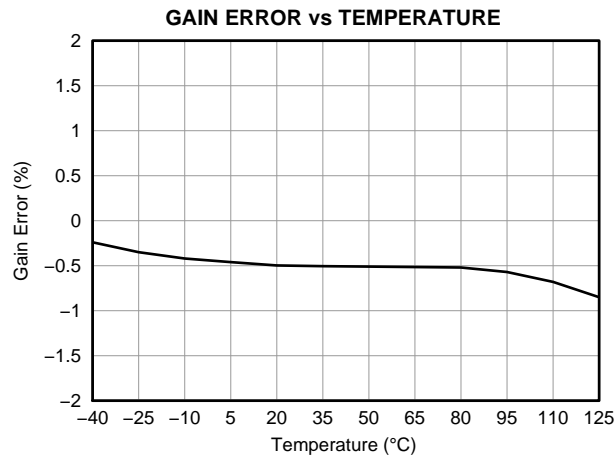


Figure 9.

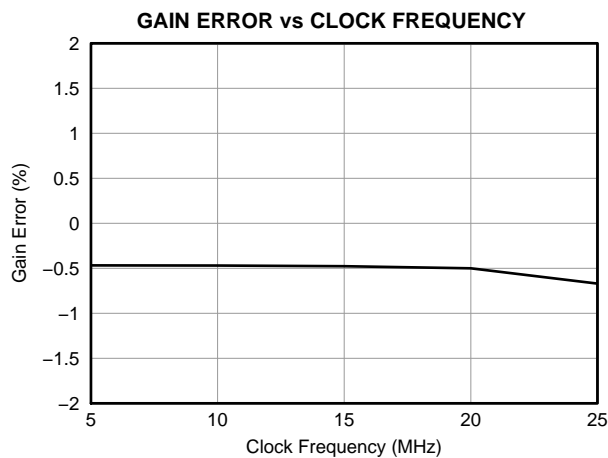


Figure 10.

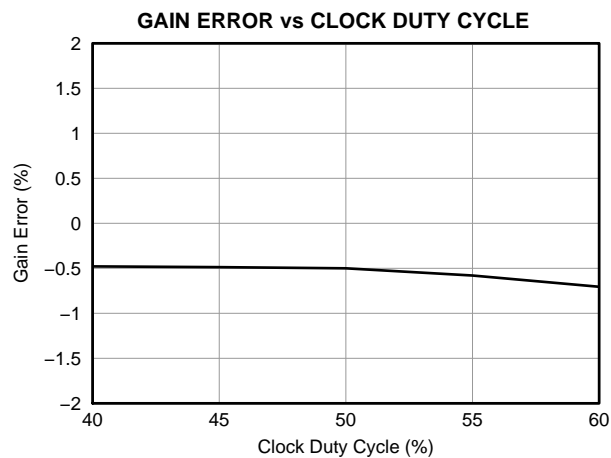


Figure 11.

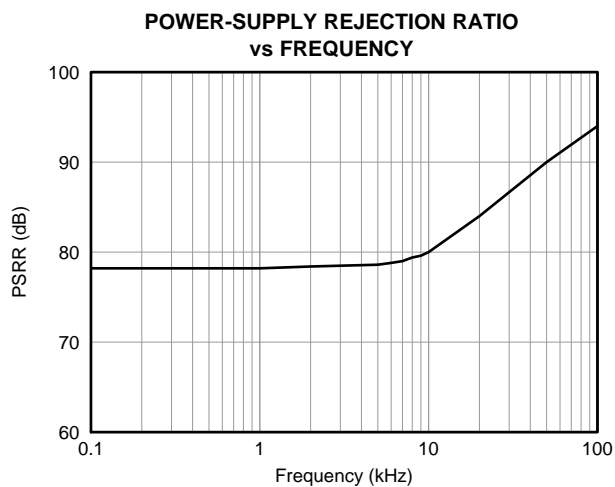


Figure 12.

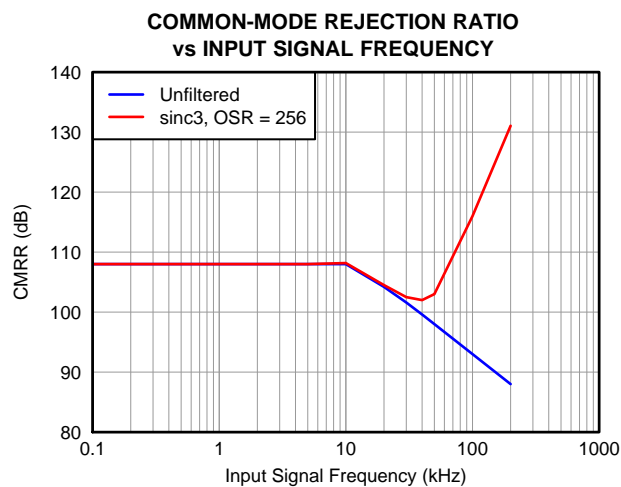


Figure 13.

## TYPICAL CHARACTERISTICS (continued)

At  $AVDD = 5\text{ V}$ ,  $DVDD = 3.3\text{ V}$ ,  $VINP = -250\text{ mV}$  to  $250\text{ mV}$ ,  $VINN = 0\text{ V}$ , and sinc<sup>3</sup> filter with OSR = 256, unless otherwise noted.

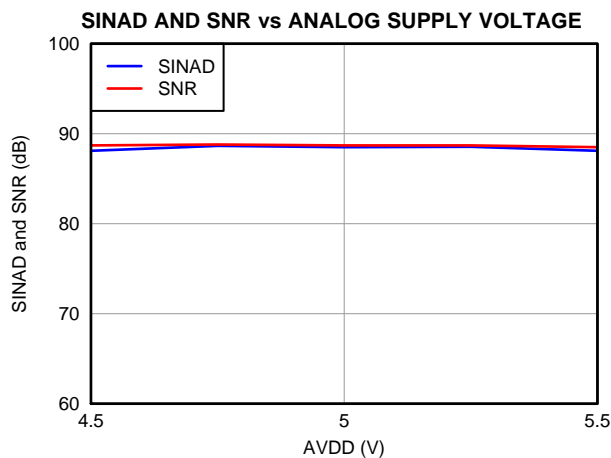


Figure 14.

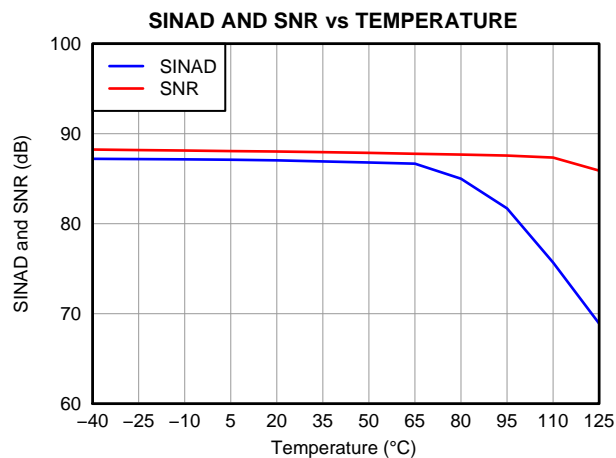


Figure 15.

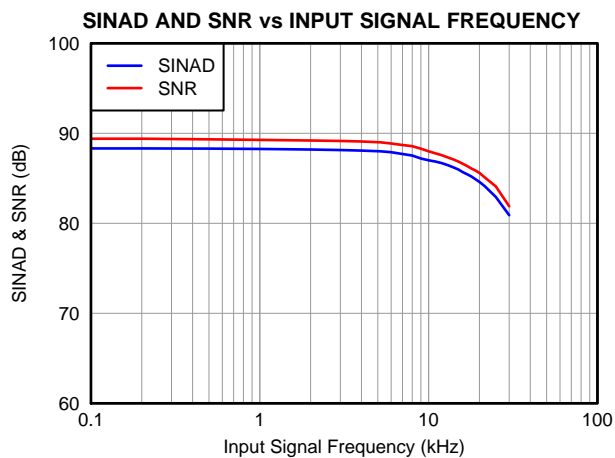


Figure 16.

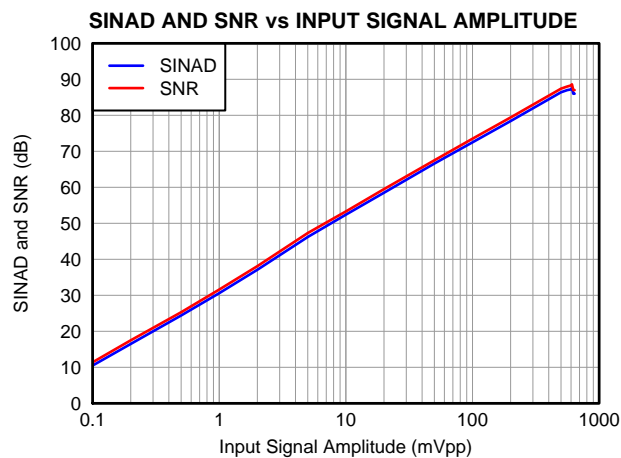


Figure 17.

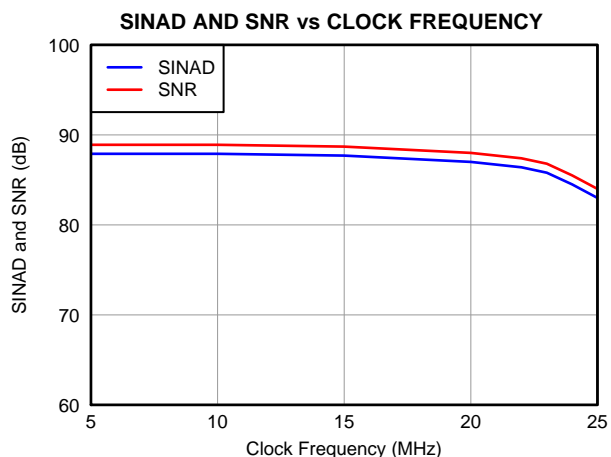


Figure 18.

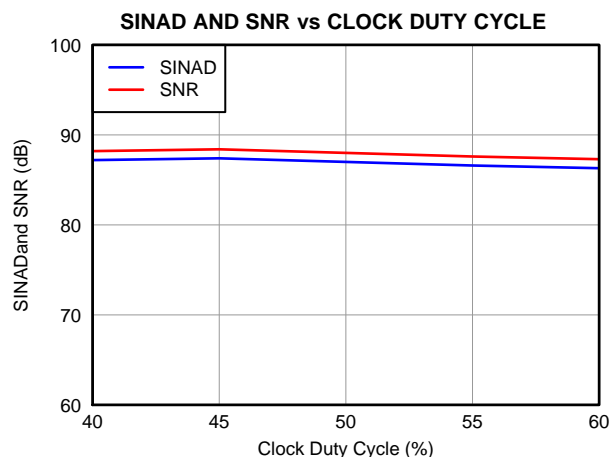


Figure 19.

## TYPICAL CHARACTERISTICS (continued)

At AVDD = 5 V, DVDD = 3.3 V, VINP = –250 mV to 250 mV, VINN = 0 V, and sinc<sup>3</sup> filter with OSR = 256, unless otherwise noted.

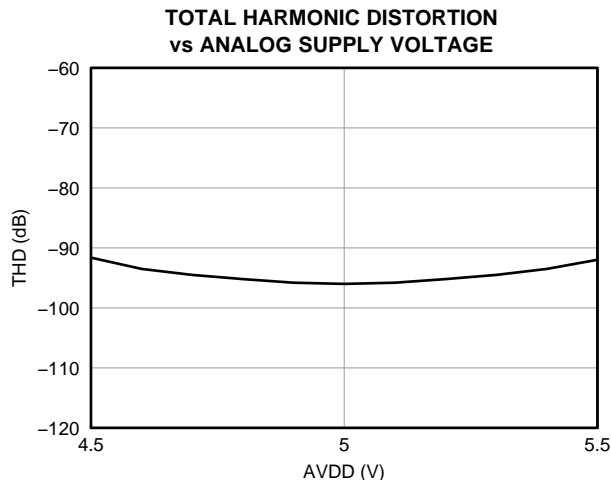


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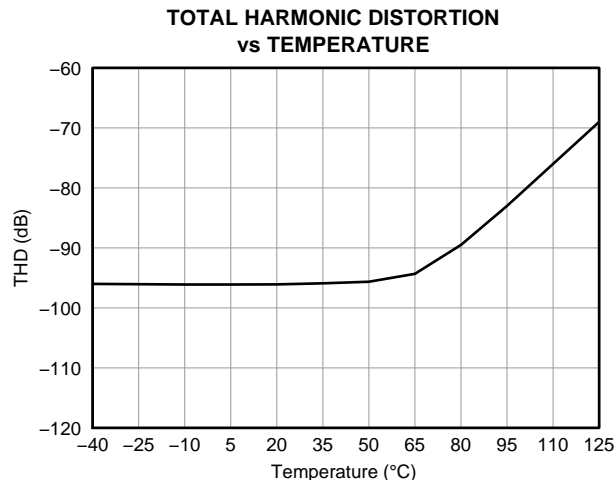


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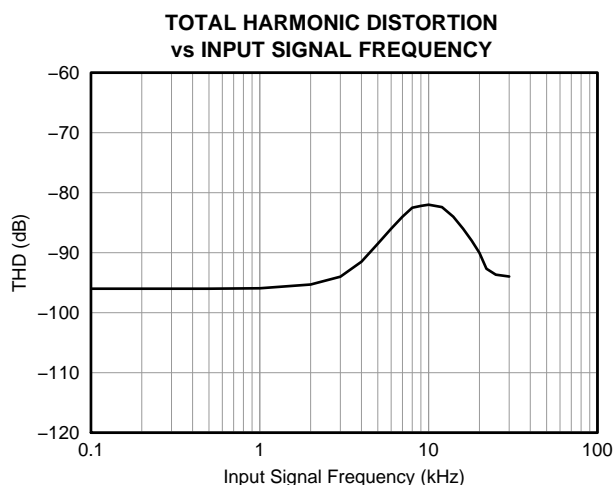


Figure 22.

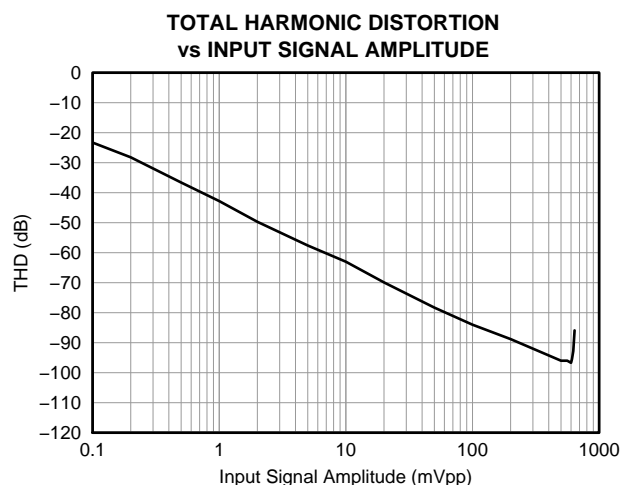


Figure 23.

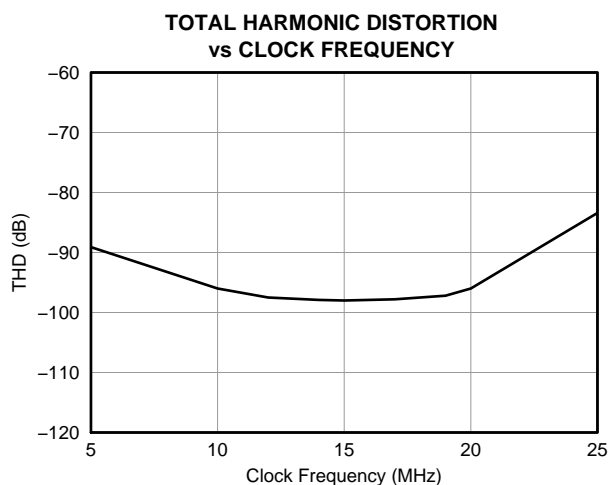


Figure 24.

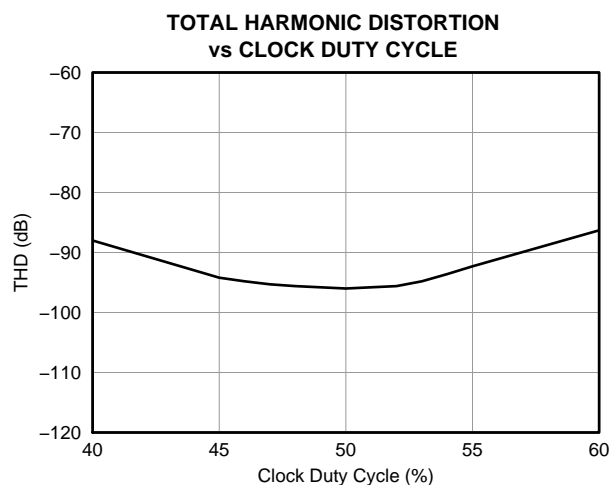


Figure 25.

## TYPICAL CHARACTERISTICS (continued)

At  $AVDD = 5\text{ V}$ ,  $DVDD = 3.3\text{ V}$ ,  $VINP = -250\text{ mV}$  to  $250\text{ mV}$ ,  $VINN = 0\text{ V}$ , and sinc<sup>3</sup> filter with OSR = 256, unless otherwise noted.

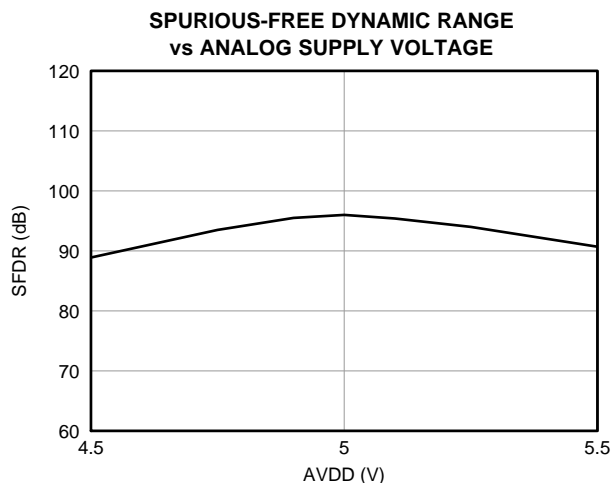


Figure 26.

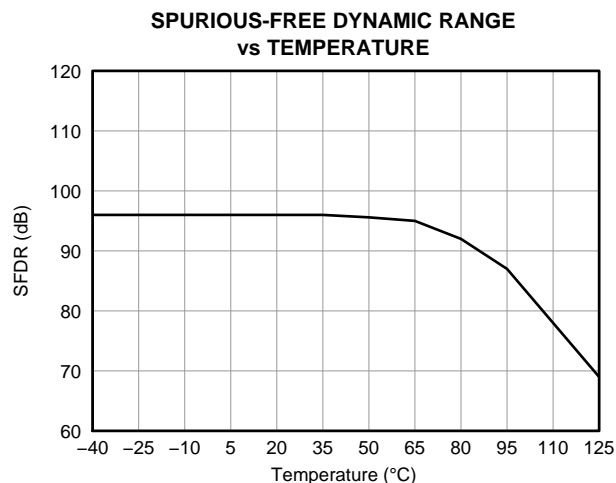


Figure 27.

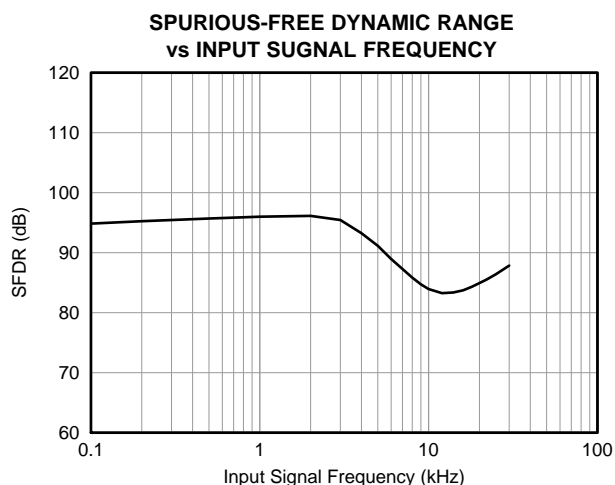


Figure 28.

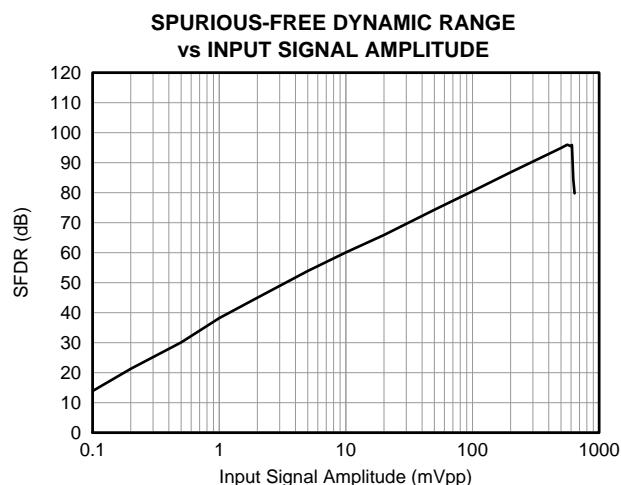


Figure 29.

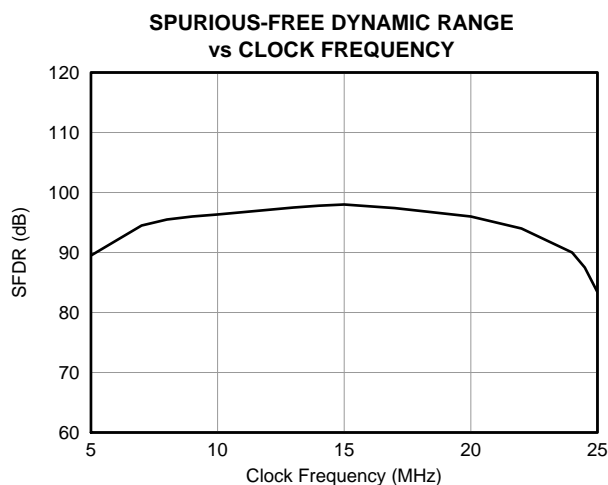


Figure 30.

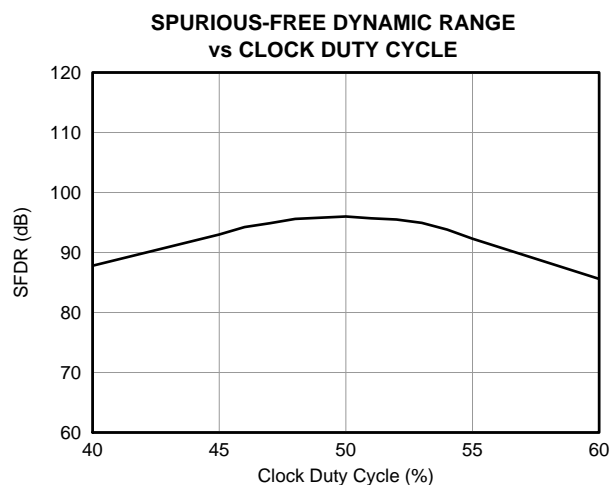


Figure 31.

## TYPICAL CHARACTERISTICS (continued)

At  $AVDD = 5\text{ V}$ ,  $DVDD = 3.3\text{ V}$ ,  $V_{INP} = -250\text{ mV}$  to  $250\text{ mV}$ ,  $V_{INN} = 0\text{ V}$ , and sinc<sup>3</sup> filter with OSR = 256, unless otherwise noted.

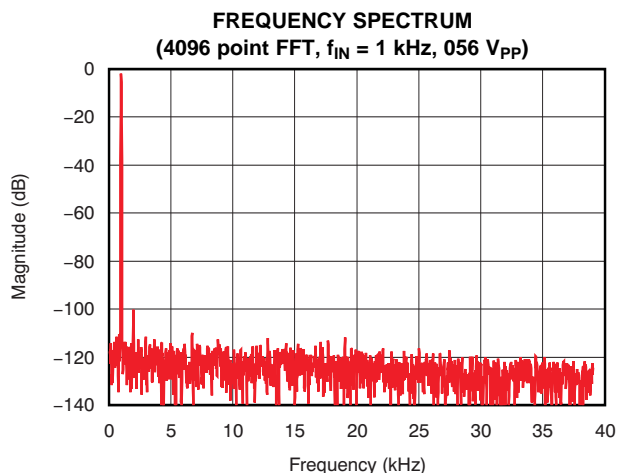


Figure 32.

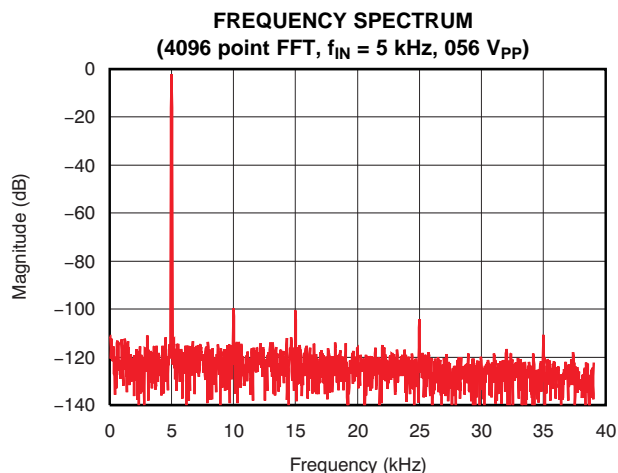


Figure 33.

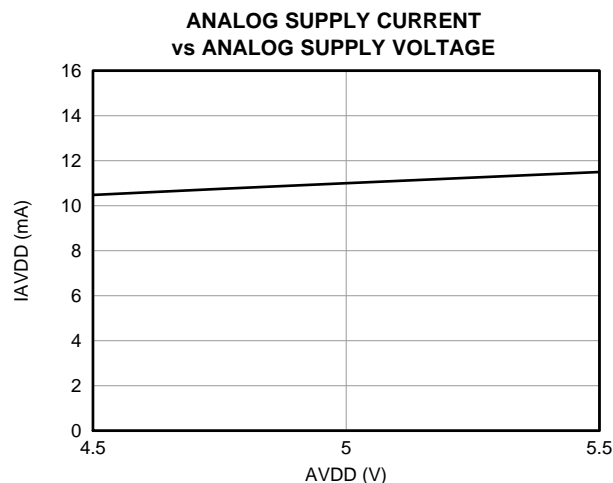


Figure 34.

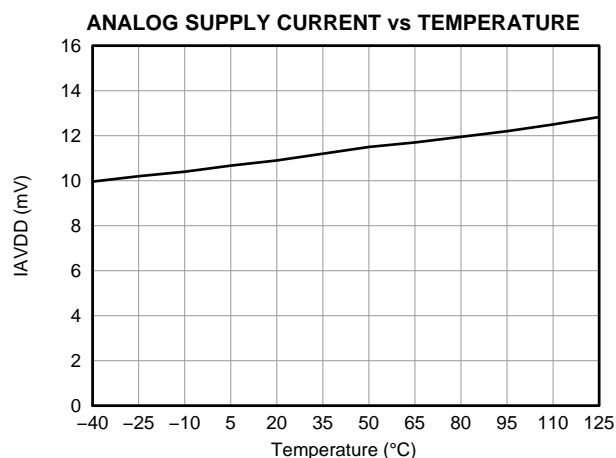


Figure 35.

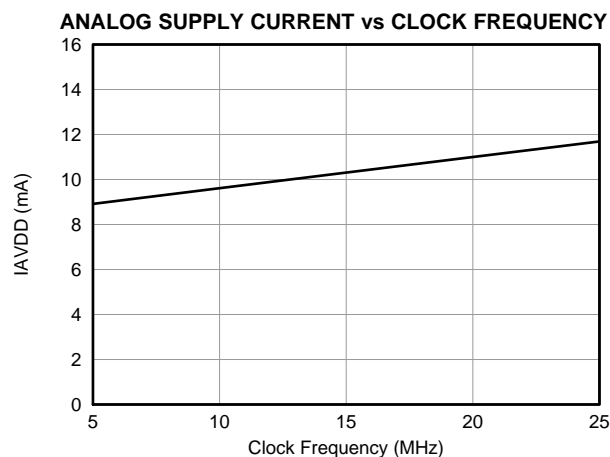


Figure 36.

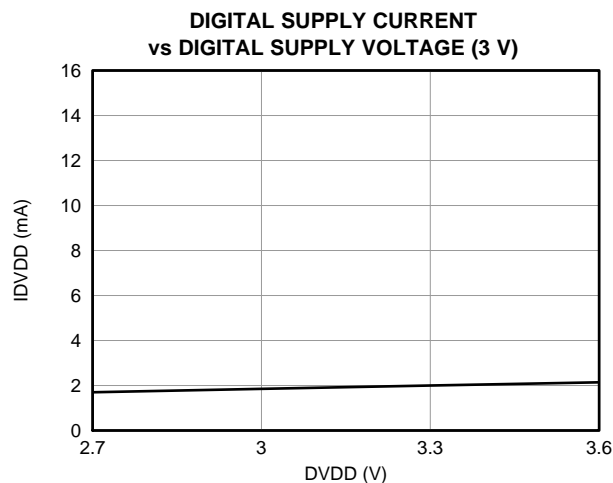


Figure 37.

## TYPICAL CHARACTERISTICS (continued)

At AVDD = 5 V, DVDD = 3.3 V, VINP = –250 mV to 250 mV, VINN = 0 V, and sinc<sup>3</sup> filter with OSR = 256, unless otherwise noted.

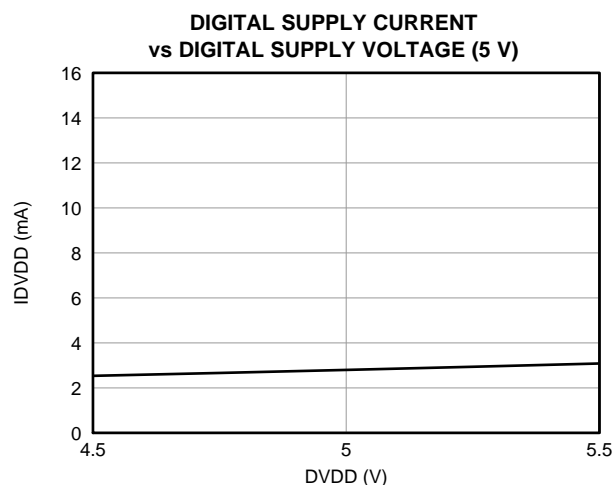


Figure 38.

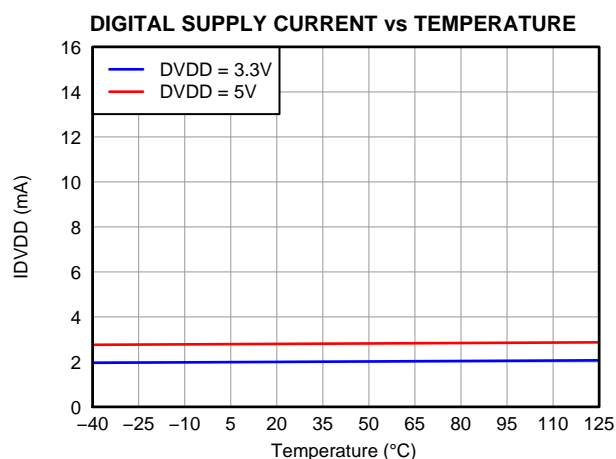


Figure 39.

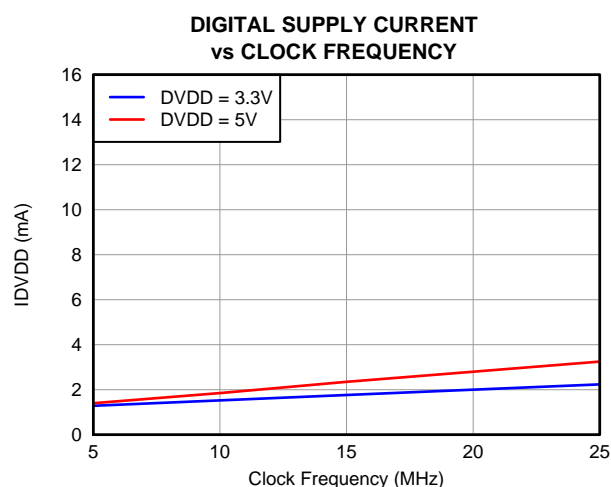


Figure 40.

## GENERAL DESCRIPTION

The AMC1204-Q1 is a single-channel, second-order, delta-sigma ( $\Delta\Sigma$ ) modulators designed for medium- to high-resolution analog-to-digital conversions. The isolated output of the converter (DATA) provides a stream of digital ones and zeros. The time average of this serial output is proportional to the analog input voltage.

Figure 41 shows a detailed block diagram of the AMC1204-Q1. The analog input range is tailored to directly accommodate a voltage drop across a shunt resistor used for current sensing. The SiO<sub>2</sub>-based capacitive isolation barrier supports a high level of magnetic field immunity as described in the application report [ISO72x Digital Isolator Magnetic-Field Immunity \(SLLA181A, available for download at www.ti.com\)](#). The external clock input simplifies the synchronization of multiple current sense channels on system level. The extended frequency range of up to 20 MHz supports higher performance levels compared to the other solutions available on the market.

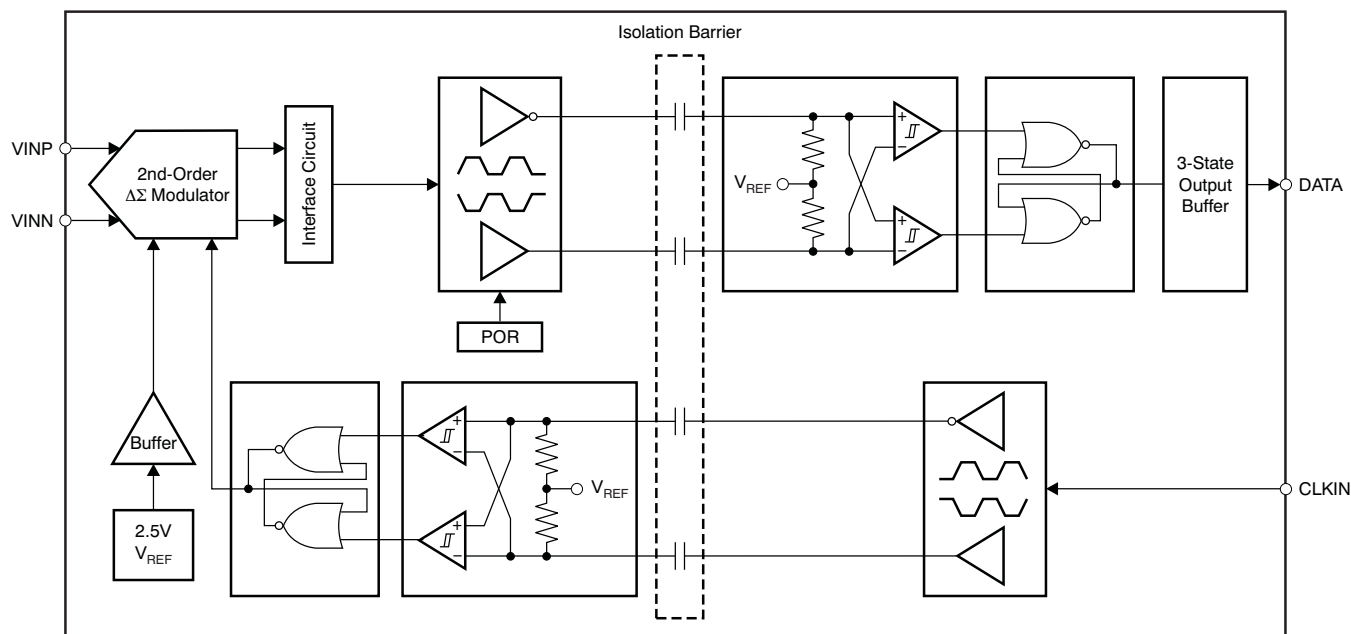


Figure 41. Detailed Block Diagram

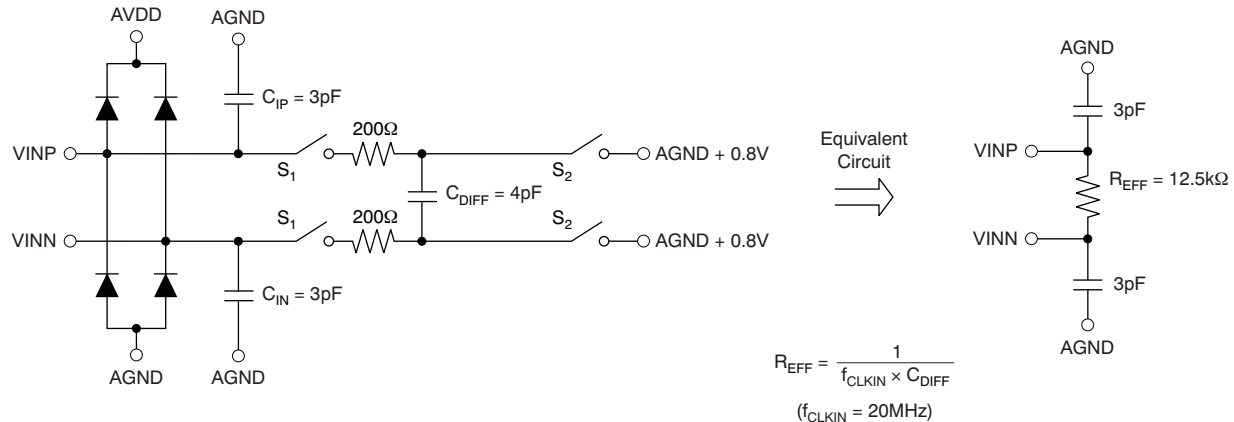
## THEORY OF OPERATION

The differential analog input of the AMC1204-Q1 is implemented with a switched-capacitor circuit. This switched-capacitor circuit implements a second-order modulator stage that digitizes the input signal into a 1-bit output stream. The externally-provided clock source at the CLKIN pin is used by the capacitor circuit and the modulator and should be in the range of 5 MHz to 22 MHz. The analog input signal is continuously sampled by the modulator and compared to an internal voltage reference. A digital stream, accurately representing the analog input voltage over time, appears at the output of the converter at the DATA pin.

## ANALOG INPUT

The AMC1204-Q1 measures the differential input signal  $V_{IN} = (V_{INP} - V_{INN})$  against the internal reference of 2.5 V using internal capacitors that are continuously charged and discharged. Figure 42 shows the simplified schematic of the ADC input circuitry; the right side of Figure 42 illustrates the input circuitry with the capacitors and switches replaced by an equivalent circuit.

In Figure 42, the  $S_1$  switches close during the input sampling phase. With the  $S_1$  switches closed,  $C_{DIFF}$  charges to the voltage difference across  $V_{INP}$  and  $V_{INN}$ . For the discharge phase, both  $S_1$  switches open first and then both  $S_2$  switches close.  $C_{DIFF}$  discharges approximately to  $AGND + 0.8\text{ V}$  during this phase. This two-phase sample/discharge cycle repeats with a period of  $t_{CLKIN} = 1/f_{CLKIN}$ .  $f_{CLKIN}$  is the operating frequency of the modulator. The capacitors  $C_{IP}$  and  $C_{IN}$  are of parasitic nature and caused by bonding wires and the internal ESD protection structure.



**Figure 42. Equivalent Analog Input Circuit**

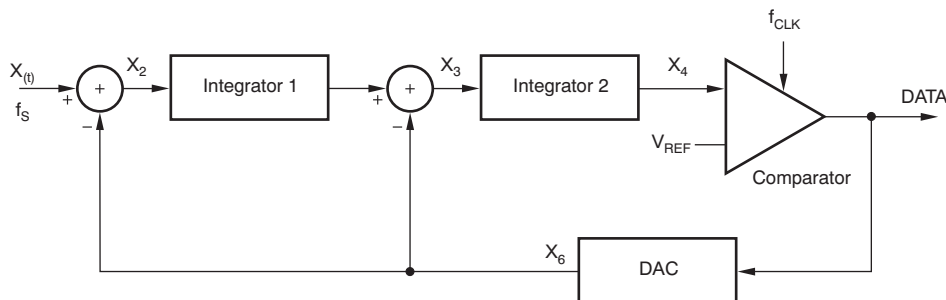
The input impedance becomes a consideration in designs with high input signal source impedance. This high impedance may cause degradation in gain, linearity, and THD. The importance of this effect, however, depends on the desired system performance. This input stage provides the mechanism to achieve low system noise, high common-mode rejection (105 dB), and excellent power-supply rejection.

There are two restrictions on the analog input signals  $V_{INP}$  and  $V_{INN}$ . First, if the input voltage exceeds the range  $AGND - 0.5\text{ V}$  to  $AVDD + 0.3\text{ V}$ , the input current must be limited to 10 mA because the input protection diodes on the front end of the converter begin to turn on. In addition, the linearity and the noise performance of the device are ensured only when the differential analog input voltage remains within  $\pm 250\text{ mV}$ .



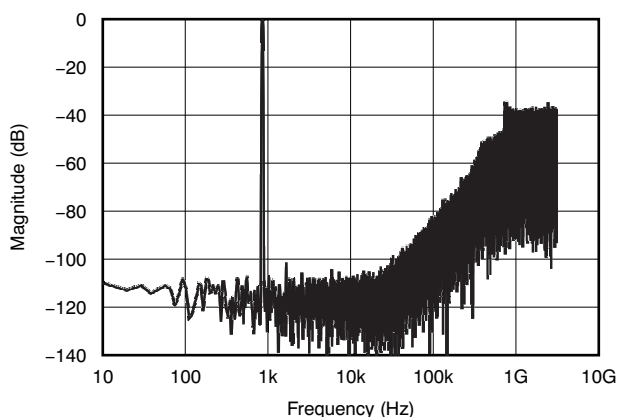
## MODULATOR

The modulator topology of the AMC1204-Q1 is fundamentally a second-order, switched-capacitor,  $\Delta\Sigma$  modulator, such as the one conceptualized in Figure 43. The analog input voltage ( $X_{(t)}$ ) and the output of the 1-bit digital-to-analog converter (DAC) are differentiated, providing an analog voltage ( $X_2$ ) at the input of the first integrator or modulator stage. The output of the first integrator is further differentiated with the DAC output; the resulting voltage ( $X_3$ ) feeds the input of the second integrator stage. When the value of the integrated signal ( $X_4$ ) at the output of the second stage equals the comparator reference voltage, the output of the comparator switches from high to low, or vice versa, depending on its previous state. In this case, the 1-bit DAC responds on the next clock pulse by changing its analog output voltage ( $X_6$ ), causing the integrators to progress in the opposite direction, while forcing the value of the integrator output to track the average of the input.



**Figure 43. Block Diagram of a Second-Order Modulator**

The modulator shifts the quantization noise to high frequencies, as shown in Figure 44; therefore, a low-pass digital filter should be used at the output of the device to increase the overall performance. This filter is also used to convert from the 1-bit data stream at a high sampling rate into a higher-bit data word at a lower rate (decimation). A digital signal processor (DSP), microcontroller ( $\mu C$ ), or field programmable gate array (FPGA) can be used to implement the filter. Another option is to use a suitable application-specific device such as the AMC1210, a four-channel digital sinc-filter.

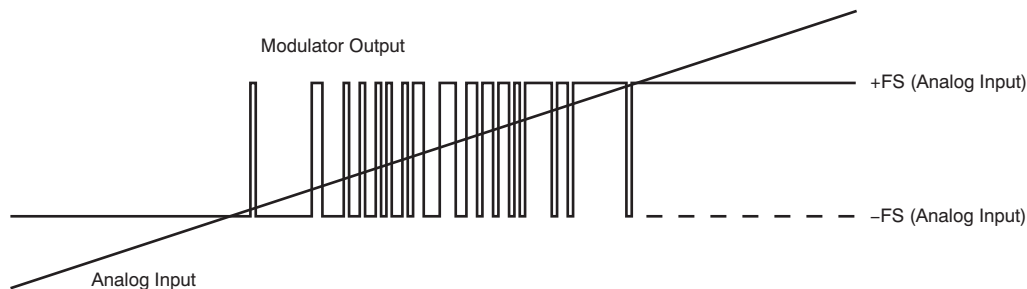


**Figure 44. Quantization Noise Shaping**

## DIGITAL OUTPUT

A differential input signal of 0 V ideally produces a stream of ones and zeros that are high 50% of the time and low 50% of the time. A differential input of 250 mV produces a stream of ones and zeros that are high 78.1% of the time. A differential input of –250 mV produces a stream of ones and zeros that are high 21.9% of the time. This is also the specified linear input range of the modulator with the performance as specified in this data sheet. The range between 250 mV and 320 mV (absolute values) is the non-linear range of the modulator. The output of the modulator clips with a stream of only zeros with an input less than or equal to –320 mV or with a stream of only ones with an input greater than or equal to 320 mV. The input voltage versus the output modulator signal is shown in [Figure 45](#).

The system clock of the AMC1204-Q1 is typically 20 MHz and is provided externally at the CLKIN pin. The data are synchronously provided at 20 MHz at the DATA output pin. The data are changing at the falling edge of CLKIN; for more details see the [Timing Information](#) section.



**Figure 45. Analog Input versus AMC1204-Q1 Modulator Output**

## FILTER USAGE

The modulator generates a bit stream that is processed by a digital filter to obtain a digital word similar to a conversion result of a conventional analog-to-digital converter (ADC). A very simple filter, built with minimal effort and hardware, is a sinc<sup>3</sup>-type filter, as shown in [Equation 1](#):

$$H(z) = \left( \frac{1 - z^{-OSR}}{1 - z^{-1}} \right)^3 \quad (1)$$

This filter provides the best output performance at the lowest hardware size (count of digital gates). For an oversampling rate (OSR) in the range of 16 to 256, this filter is a good choice. All the characterization in this document is also done with a sinc<sup>3</sup> filter with OSR = 256 and an output word width of 16 bits.

In a sinc<sup>3</sup> filter response (shown in Figure 46 and Figure 47), the location of the first notch occurs at the frequency of output data rate  $f_{\text{DATA}} = f_{\text{CLK}}/\text{OSR}$ . The –3 dB point is located at half the Nyquist frequency or  $f_{\text{DATA}}/4$ . For some applications, it may be necessary to use another filter type with different frequency response. Performance can be improved, for example, by using a cascaded filter structure. The first decimation stage could be built of a sinc<sup>3</sup> filter with a low OSR and the second stage using a high-order filter.

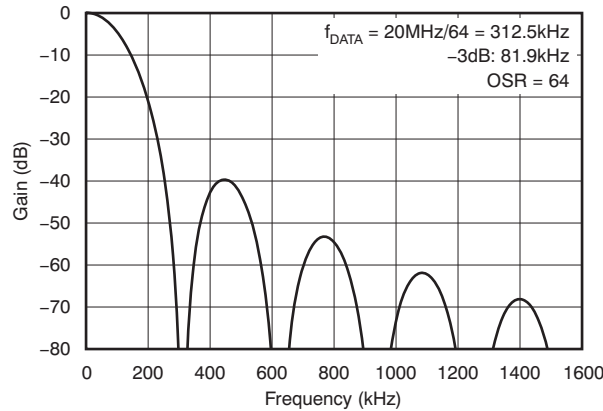


Figure 46. Frequency Response of the Sinc<sup>3</sup> Filter

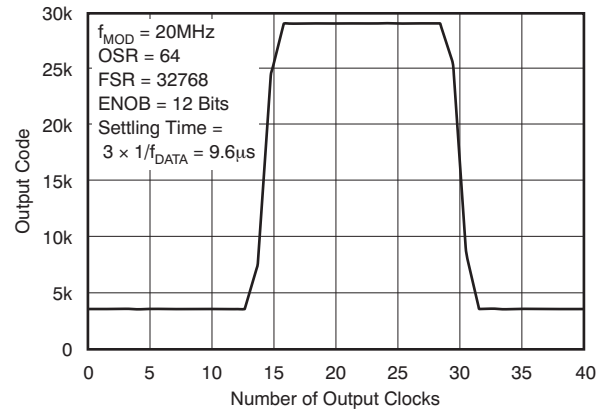


Figure 47. Pole Response of the Sinc<sup>3</sup> Filter

The effective number of bits (ENOB) is often used to compare the performance of ADCs and  $\Delta\Sigma$  modulators. Figure 48 illustrates the ENOB of the AMC1204-Q1 with different oversampling ratios. In this data sheet, this number is calculated from SNR using Equation 2:

$$\text{SNR} = 1.76\text{dB} + 6.02\text{dB} \times \text{ENOB} \quad (2)$$

In motor control applications, a very fast response time for overcurrent detection is required. The time for fully settling the filter depends on its order; that is, a sinc<sup>3</sup> filter requires three data clocks for full settling (with  $f_{\text{DATA}} = f_{\text{CLK}}/\text{OSR}$ ). Therefore, for overcurrent protection, filter types other than sinc<sup>3</sup> might be a better choice; an alternative is the sinc<sup>2</sup> filter. Figure 49 compares the settling times of different filter orders with sincfast being a modified sinc<sup>2</sup> filter with behavior as shown in Equation 3.

$$H(z) = \left( \frac{1 - z^{-\text{OSR}}}{1 - z^{-1}} \right)^2 (1 + z^{-2\text{OSR}}) \quad (3)$$

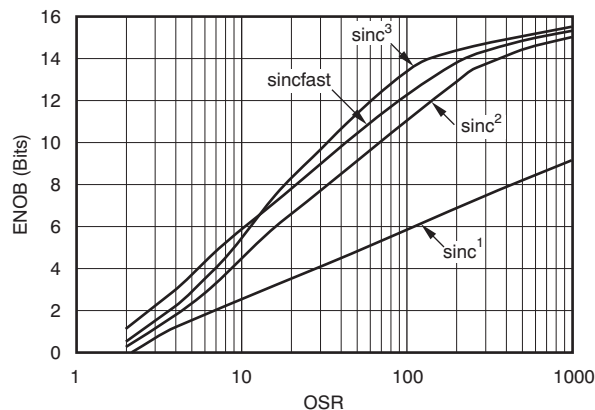


Figure 48. Measured Effective Number of Bits versus Oversampling Ratio

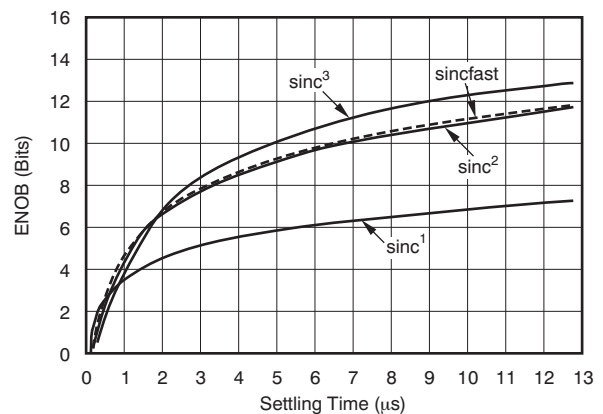


Figure 49. Measured Effective Number of Bits versus Settling Time

An example code for an implementation of a sinc<sup>3</sup> filter in an FPGA follows. For more information, see the application note [Combining ADS1202 with FPGA Digital Filter for Current Measurement in Motor Control Applications \(SBAA094\)](#), available for download at [www.ti.com](http://www.ti.com).

```

library IEEE;
use IEEE.std_logic_1164.all;
use IEEE.std_logic_unsigned.all;

entity FLT is
  port(RESN, MOUT, MCLK, CNR : in std_logic;
        CN5 : out std_logic_vector(23 downto 0));
end FLT;

architecture RTL of FLT is
  signal DN0, DN1, DN3, DN5 : std_logic_vector(23 downto 0);
  signal CN1, CN2, CN3, CN4 : std_logic_vector(23 downto 0);
  signal DELTA1 : std_logic_vector(23 downto 0);
begin

  process(MCLK, RESN)
  begin
    if RESN = '0' then
      DELTA1 <= (others => '0');
    elsif MCLK'event and MCLK = '1' then
      if MOUT = '1' then
        DELTA1 <= DELTA1 + 1;
      end if;
    end if;
  end process;

  process(RESN, MCLK)
  begin
    if RESN = '0' then
      CN1 <= (others => '0');
      CN2 <= (others => '0');
    elsif MCLK'event and MCLK = '1' then
      CN1 <= CN1 + DELTA1;
      CN2 <= CN2 + CN1;
    end if;
  end process;

  process(RESN, CNR)
  begin
    if RESN = '0' then
      DN0 <= (others => '0');
      DN1 <= (others => '0');
      DN3 <= (others => '0');
      DN5 <= (others => '0');
    elsif CNR'event and CNR = '1' then
      DN0 <= CN2;
      DN1 <= DN0;
      DN3 <= CN3;
      DN5 <= CN4;
    end if;
  end process;

  CN3 <= DN0 - DN1;
  CN4 <= CN3 - DN3;
  CN5 <= CN4 - DN5;

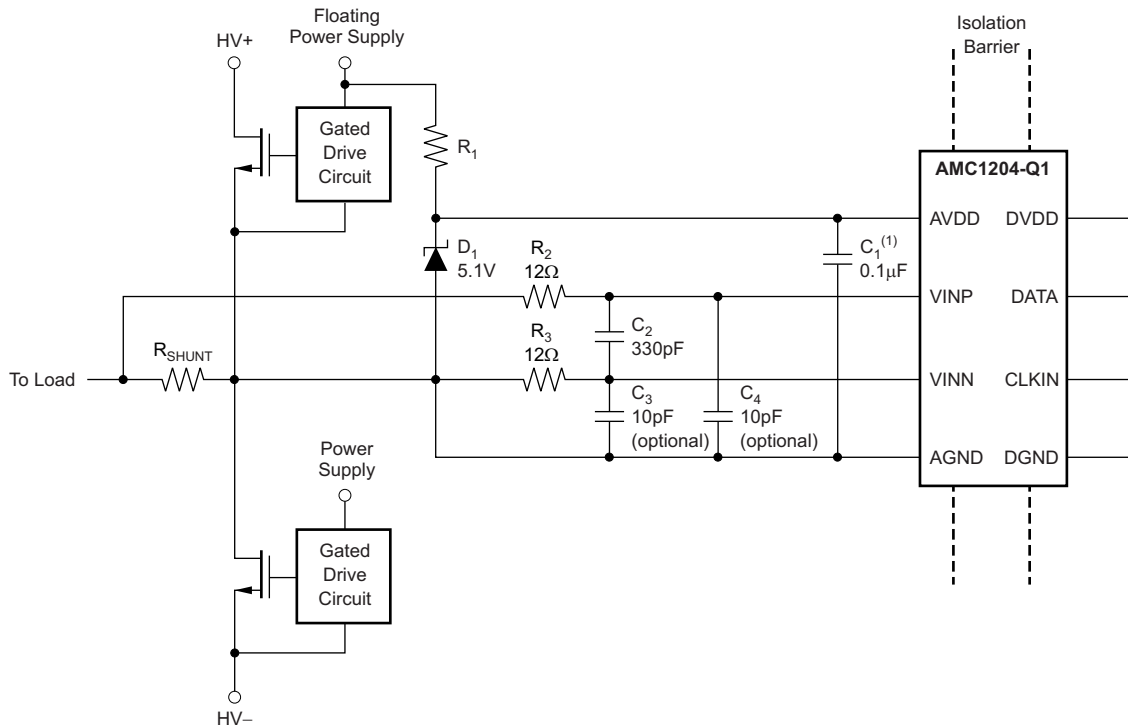
end RTL;

```

## APPLICATION INFORMATION

A typical operation of the AMC1204-Q1 in a motor control application is shown in Figure 50. Measurement of the motor phase current is done via the shunt resistor  $R_{SHUNT}$  (in this case, a two-terminal shunt). For better performance, the differential signal is filtered using RC filters (components  $R_2$ ,  $R_3$ , and  $C_2$ ). Optionally,  $C_3$  and  $C_4$  can be used to reduce charge dumping from the inputs. In this case, care should be taken when choosing the quality of these capacitors—mismatch in values of these capacitors leads to a common-mode error at the input of the modulator.

The high-side power supply (AVDD) for the AMC1204-Q1 is derived from the power supply of the upper gate driver. For lowest cost, a zener diode can be used to limit the voltage to  $5\text{ V} \pm 10\%$ . A decoupling capacitor of  $0.1\text{ }\mu\text{F}$  is recommended for filtering this power-supply path. This capacitor ( $C_1$  in Figure 50) should be placed as close as possible to the AVDD pin for best performance. If better filtering is required, an additional  $1\text{ }\mu\text{F}$  to  $10\text{ }\mu\text{F}$  capacitor can be used. The floating ground reference AGND is derived from the end of the shunt resistor, which is connected to the negative input (VINN) of the AMC1204-Q1. If a four-terminal shunt is used, the inputs of AMC1204-Q1 are connected to the inner leads, while AGND is connected to one of the outer leads of the shunt. Both digital signals, CLKIN and DATA, can be directly connected to a digital filter (for example, the AMC1210); see Figure 51.

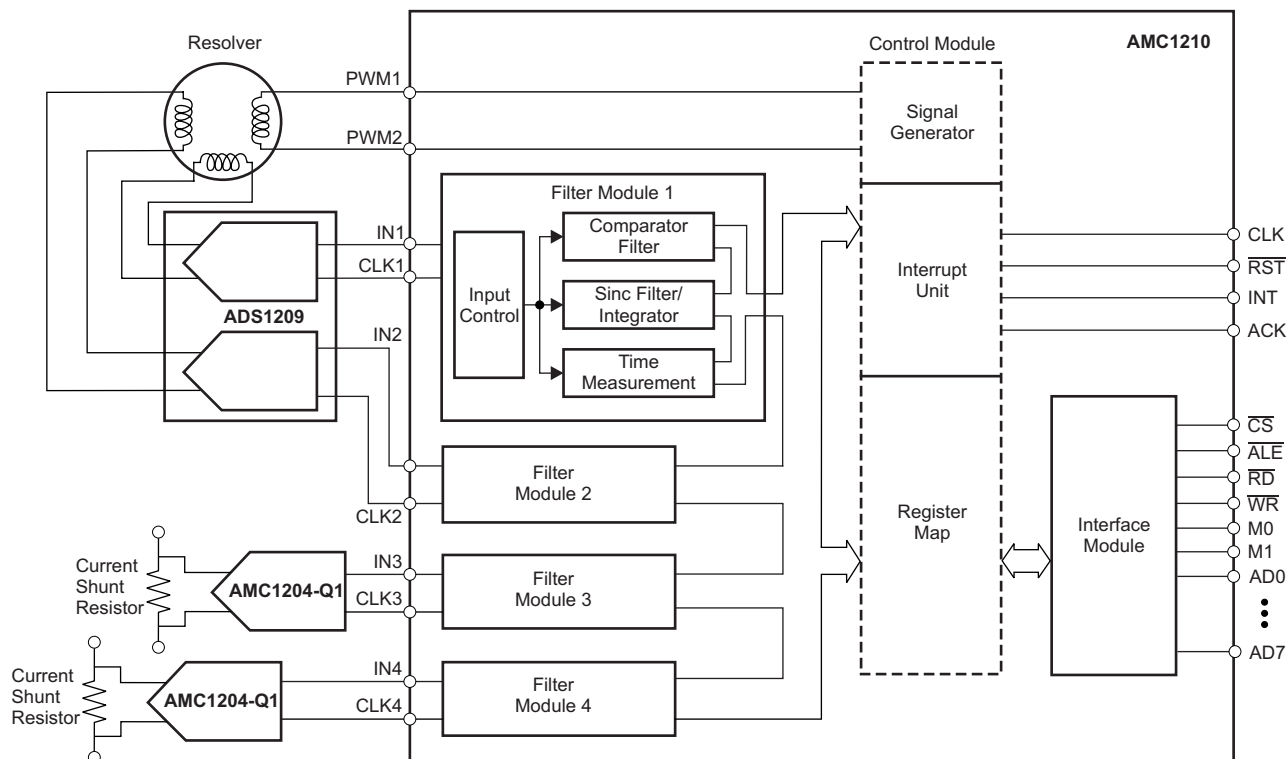


(1) Place  $C_1$  close to the AMC1204-Q1.

Figure 50. Typical Application Diagram

Figure 51 shows an example of two AMC1204-Q1 devices and one ADS1209 (a dual-channel, 10 MHz, non-isolated modulator) connected to an AMC1210, building the entire analog front-end of a resolver-based motor control application.

For detailed information on the ADS1209 and AMC1210, visit the respective device product folders at [www.ti.com](http://www.ti.com).



**Figure 51. Example of a Resolver-Based Motor Control Analog Front-End**

A layout recommendation showing the critical placement of the decoupling capacitor on the high-side and placement of the other components required by the AMC1204-Q1 is presented in [Figure 52](#).

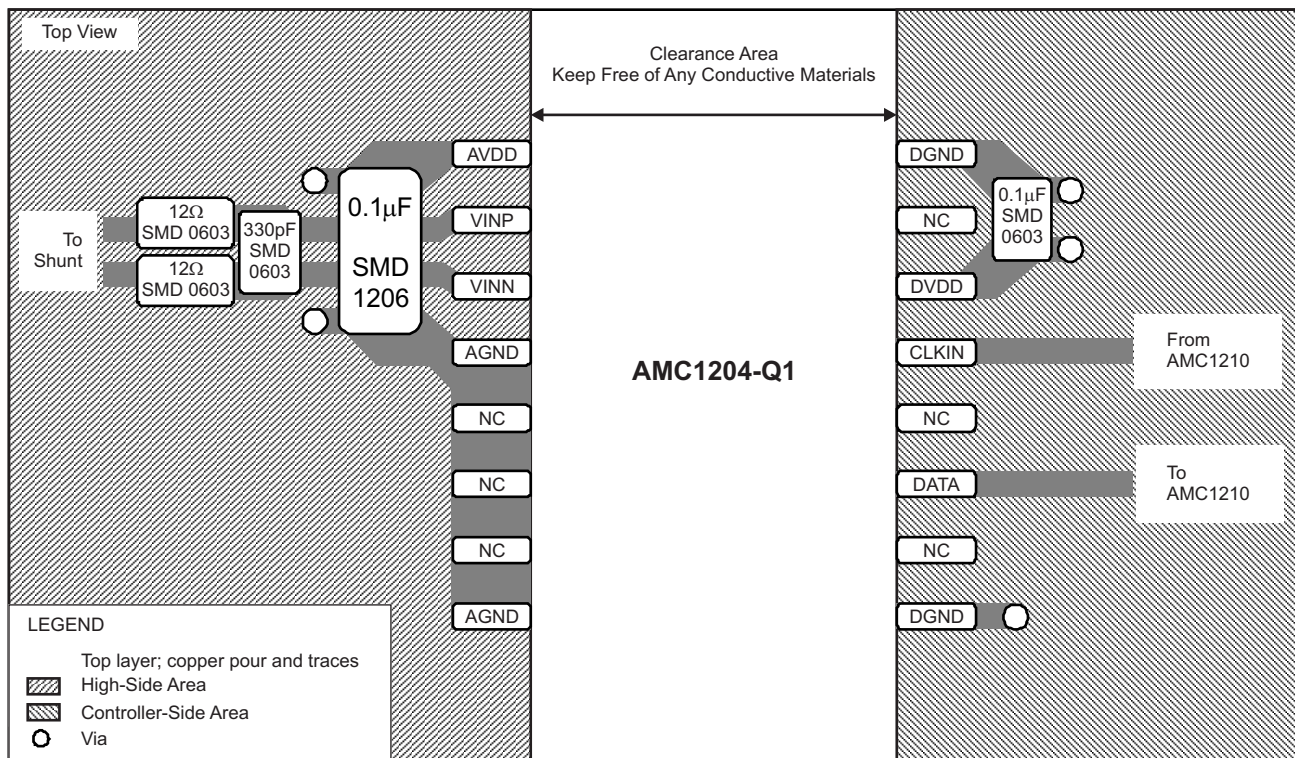
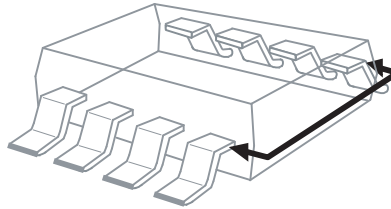


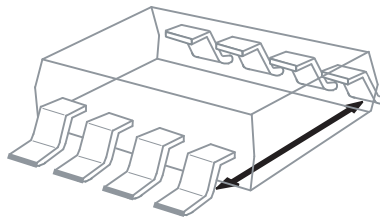
Figure 52. Recommended Layout

## ISOLATION GLOSSARY

**Creepage Distance:** The shortest path between two conductive input to output leads measured along the surface of the insulation. The shortest distance path is found around the end of the package body.



**Clearance:** The shortest distance between two conductive input to output leads measured through air (line of sight).



**Input-to-Output Barrier Capacitance:** The total capacitance between all input terminals connected together, and all output terminals connected together.

**Input-to-Output Barrier Resistance:** The total resistance between all input terminals connected together, and all output terminals connected together.

**Primary Circuit:** An internal circuit directly connected to an external supply mains or other equivalent source that supplies the primary circuit electric power.

**Secondary Circuit:** A circuit with no direct connection to primary power that derives its power from a separate isolated source.

**Comparative Tracking Index (CTI):** CTI is an index used for electrical insulating materials. It is defined as the numerical value of the voltage that causes failure by tracking during standard testing. Tracking is the process that produces a partially conducting path of localized deterioration on or through the surface of an insulating material as a result of the action of electric discharges on or close to an insulation surface. The higher CTI value of the insulating material, the smaller the minimum creepage distance.

Generally, insulation breakdown occurs either through the material, over its surface, or both. Surface failure may arise from flashover or from the progressive degradation of the insulation surface by small localized sparks. Such sparks are the result of the breaking of a surface film of conducting contaminant on the insulation. The resulting break in the leakage current produces an overvoltage at the site of the discontinuity, and an electric spark is generated. These sparks often cause carbonization on insulation material and lead to a carbon track between points of different potential. This process is known as tracking.

### Insulation:

*Operational insulation*—Insulation needed for the correct operation of the equipment.

*Basic insulation*—Insulation to provide basic protection against electric shock.

*Supplementary insulation*—Independent insulation applied in addition to basic insulation in order to ensure protection against electric shock in the event of a failure of the basic insulation.

*Double insulation*—Insulation comprising both basic and supplementary insulation.

*Reinforced insulation*—A single insulation system that provides a degree of protection against electric shock equivalent to double insulation.



**Pollution Degree:**

*Pollution Degree 1*—No pollution, or only dry, nonconductive pollution occurs. The pollution has no influence on device performance.

*Pollution Degree 2*—Normally, only nonconductive pollution occurs. However, a temporary conductivity caused by condensation is to be expected.

*Pollution Degree 3*—Conductive pollution, or dry nonconductive pollution that becomes conductive because of condensation, occurs. Condensation is to be expected.

*Pollution Degree 4*—Continuous conductivity occurs as a result of conductive dust, rain, or other wet conditions.

**Installation Category:**

*Overvoltage Category*—This section is directed at insulation coordination by identifying the transient overvoltages that may occur, and by assigning four different levels as indicated in IEC 60664.

1. Signal Level: Special equipment or parts of equipment.
2. Local Level: Portable equipment, etc.
3. Distribution Level: Fixed installation.
4. Primary Supply Level: Overhead lines, cable systems.

Each category should be subject to smaller transients than the previous category.

REVISION HISTORY

| Changes from Revision A (October, 2012) to Revision B   | Page |
|---|------|
| • Changed $V_{PEAK}$ from 4000 to 4250. ....  | 1    |
| • Changed $V_{PEAK}$ from 4000 to 4250. ....  | 1    |
| • Changed $V_{IOTM}$ with $t = 60$ s (qualification test) test condition from 4000 to 4250. ....  | 4    |
| • Changed $V_{IOTM}$ with $t = 1$ s (100% production test) test condition from 4000 to 5100. .... | 4    |

## PACKAGING INFORMATION

| Orderable part number         | Status<br>(1) | Material type<br>(2) | Package   Pins | Package qty   Carrier | RoHS<br>(3) | Lead finish/<br>Ball material<br>(4) | MSL rating/<br>Peak reflow<br>(5) | Op temp (°C) | Part marking<br>(6) |
|-------------------------------|---------------|----------------------|----------------|-----------------------|-------------|--------------------------------------|-----------------------------------|--------------|---------------------|
| <a href="#">AMC1204QDWRQ1</a> | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 125   | AMC1204Q            |
| AMC1204QDWRQ1.A               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | Yes         | NIPDAU                               | Level-3-260C-168 HR               | -40 to 125   | AMC1204Q            |
| AMC1204QDWRQ1.B               | Active        | Production           | SOIC (DW)   16 | 2000   LARGE T&R      | -           | Call TI                              | Call TI                           | -40 to 125   |                     |

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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### OTHER QUALIFIED VERSIONS OF AMC1204-Q1 :

- Catalog : [AMC1204](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

## TAPE AND REEL INFORMATION



\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------|--------------|-----------------|------|------|--------------------|--------------------|---------|---------|---------|---------|--------|---------------|
| AMC1204QDWRQ1 | SOIC         | DW              | 16   | 2000 | 330.0              | 16.4               | 10.75   | 10.7    | 2.7     | 12.0    | 16.0   | Q1            |

## TAPE AND REEL BOX DIMENSIONS



\*All dimensions are nominal

| Device        | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|---------------|--------------|-----------------|------|------|-------------|------------|-------------|
| AMC1204QDWRQ1 | SOIC         | DW              | 16   | 2000 | 353.0       | 353.0      | 32.0        |

## GENERIC PACKAGE VIEW

**DW 16**

**SOIC - 2.65 mm max height**

7.5 x 10.3, 1.27 mm pitch

SMALL OUTLINE INTEGRATED CIRCUIT

This image is a representation of the package family, actual package may vary.  
Refer to the product data sheet for package details.



4224780/A



DW0016A

# PACKAGE OUTLINE

## SOIC - 2.65 mm max height

SOIC



4220721/A 07/2016

### NOTES:

1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.



# EXAMPLE BOARD LAYOUT

DW0016A

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE  
SCALE:7X



SOLDER MASK DETAILS

4220721/A 07/2016

NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

# EXAMPLE STENCIL DESIGN

DW0016A

SOIC - 2.65 mm max height

SOIC



SOLDER PASTE EXAMPLE  
BASED ON 0.125 mm THICK STENCIL  
SCALE:7X

4220721/A 07/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.



DW0016B

# PACKAGE OUTLINE

## SOIC - 2.65 mm max height

SOIC



4221009/B 07/2016

### NOTES:

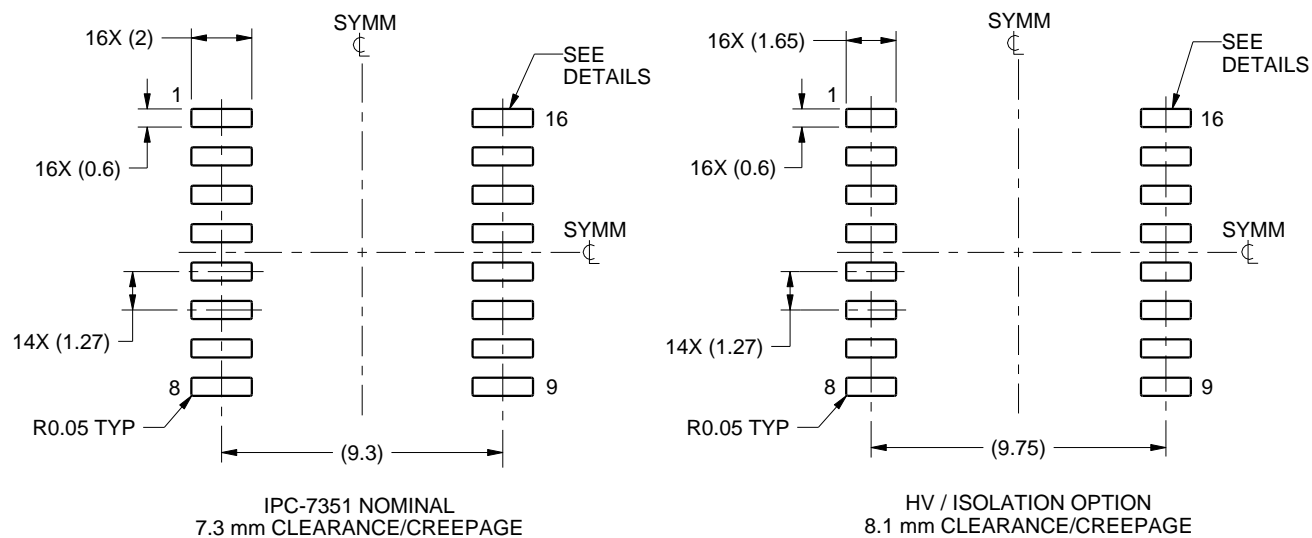
1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm, per side.
4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm, per side.
5. Reference JEDEC registration MS-013.

# EXAMPLE BOARD LAYOUT

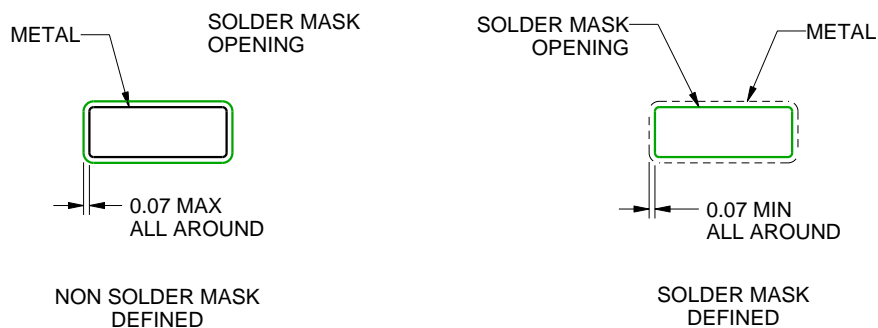
DW0016B

SOIC - 2.65 mm max height

SOIC



LAND PATTERN EXAMPLE  
SCALE:4X



SOLDER MASK DETAILS

4221009/B 07/2016

NOTES: (continued)

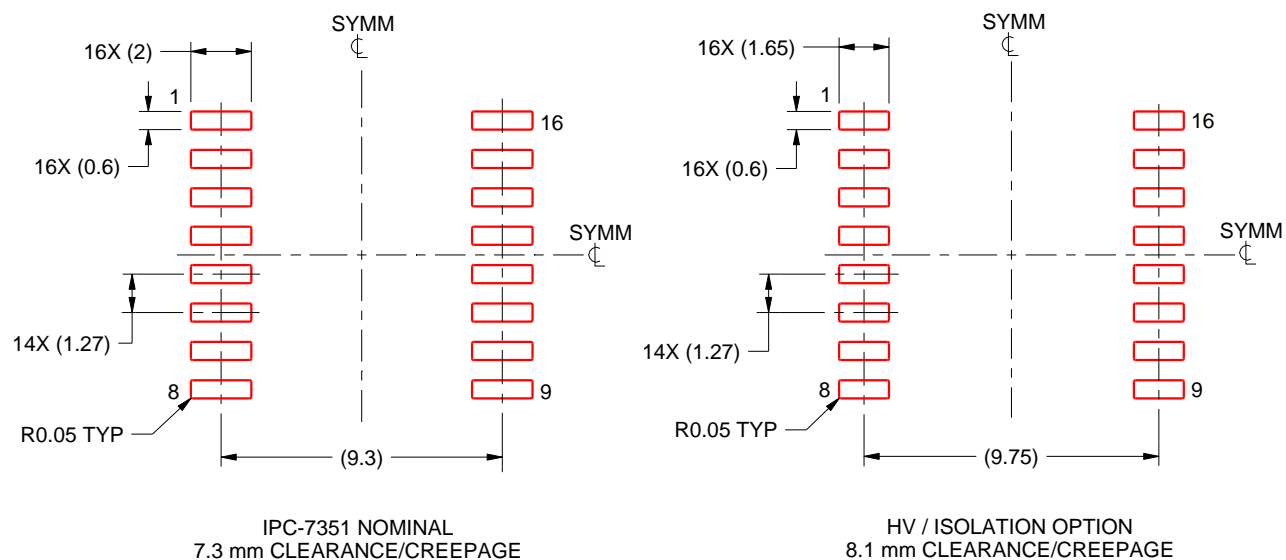
6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

**DW0016B**

### SOIC - 2.65 mm max height

SOIC



**SOLDER PASTE EXAMPLE**  
**BASED ON 0.125 mm THICK STENCIL**  
**SCALE:4X**

4221009/B 07/2016

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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